



**THE DATASHEET OF
LT1997HDF-3#PBF**



Precision, Wide Voltage Range Gain Selectable Amplifier

FEATURES

- Pin Configurable as a Difference Amplifier, Inverting Amplifier or Noninverting Amplifier
- 91dB Minimum DC CMRR (Gain = 1)
- 65dB AC CMRR (at 100kHz, Gain = 1)
- 0.006% (60ppm) Maximum Gain Error (Gain = 1)
- 1ppm/°C Maximum Gain Error Drift
- 2ppm Maximum Gain Nonlinearity
- ±160V Common Mode Voltage Range
- Wide Supply Voltage Range: 3.3V to 50V
- Rail-to-Rail Output
- 350µA Supply Current
- 60µV Maximum Op Amp Offset Voltage
- 1.1MHz -3dB Bandwidth (Gain = 1)
- Low-Power Shutdown: 20µA
- Space-Saving MSOP and DFN Packages

APPLICATIONS

- High Side or Low Side Current Sensing
- Bidirectional Wide Common Mode Range Current Sensing
- High Voltage to Low Voltage Level Translation
- Industrial Data-Acquisition Front-Ends
- Replacement for Isolation Circuits
- Differential to Single-Ended Conversion

DESCRIPTION

The LT[®]1997-3 combines a precision operational amplifier with highly-matched resistors to form a one-chip solution for accurately amplifying voltages. Gains from -13 to +14 with accuracy of 0.006% (60ppm) can be achieved using no external components. The LT1997-3 is particularly well suited for use as a difference amplifier, where the excellent resistor matching results in a common mode rejection ratio of greater than 91dB.

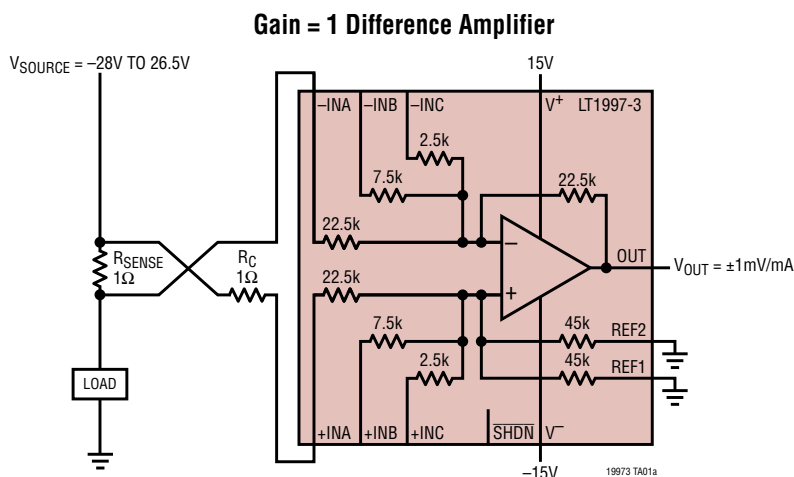
The amplifier features a 60µV maximum input offset voltage and a -3dB bandwidth of 1.1MHz (Gain = 1). The LT1997-3 operates from any supply voltage from 3.3V to 50V and draws only 350µA supply current. The output typically swings to within 100mV of either supply rail.

The resistors maintain their excellent matching over temperature; the matching temperature coefficient is guaranteed less than 1ppm/°C. The resistors are extremely linear with voltage, resulting in a gain nonlinearity of less than 2ppm.

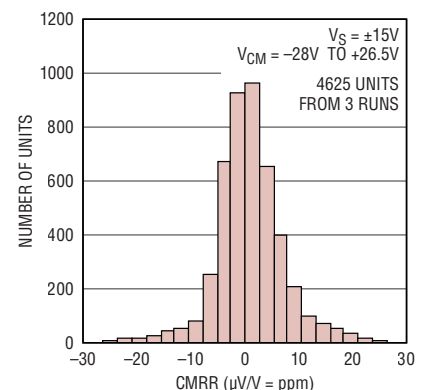
The LT1997-3 is fully specified at 5V and ±15V supplies and from -40°C to 125°C. The device is available in space saving 16-lead MSOP and 4mm × 4mm DFN14 packages.

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TYPICAL APPLICATION



Typical Distribution of CMRR (G = 1)



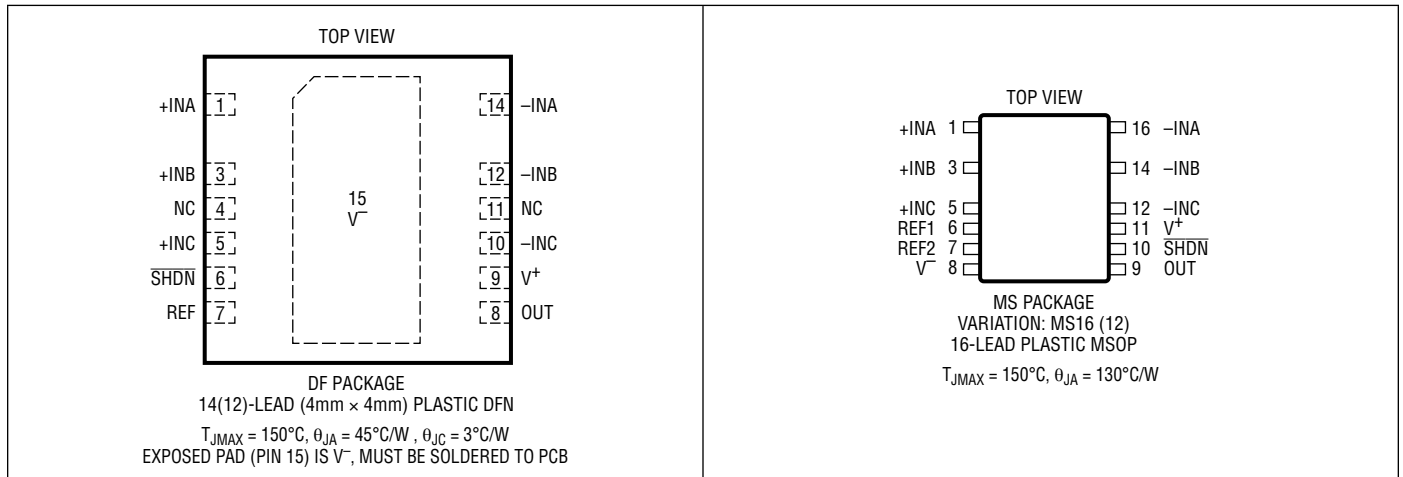
ABSOLUTE MAXIMUM RATINGS

(Note 1)

| | |
|---|----------------------------------|
| Supply Voltages (V^+ to V^-)..... | 60V |
| +INA, -INA (Note 2)..... | $V^- \pm 160V$ |
| +INB, -INB, +INC, -INC (Note 2)..... | $(V^- + 80V)$ to $(V^- - 0.3V)$ |
| REF, REF1, REF2..... | $(V^- + 60V)$ to $(V^- - 0.3V)$ |
| SHDN..... | $(V^+ + 0.3V)$ to $(V^- - 0.3V)$ |
| Output Current (Continuous) (Note 6)..... | 50mA |

| | |
|--|-------------------|
| Output Short-Circuit Duration (Note 3)..... | Thermally Limited |
| Temperature Range (Notes 4, 5) LT1997I-3..... | -40 to 85°C |
| LT1997H-3..... | -40 to 125°C |
| Maximum Junction Temperature..... | 150°C |
| Storage Temperature Range..... | -65 to 150°C |
| MSOP Lead Temperature (Soldering, 10 sec)..... | 300°C |

PIN CONFIGURATION



ORDER INFORMATION <http://www.linear.com/product/LT1997-3#orderinfo>

| LEAD FREE FINISH | TAPE AND REEL | PART MARKING* | PACKAGE DESCRIPTION | SPECIFIED TEMPERATURE RANGE |
|------------------|-------------------|---------------|---------------------------------|-----------------------------|
| LT1997IDF-3#PBF | LT1997IDF-3#TRPBF | 19973 | 14-Lead (4mm × 4mm) Plastic DFN | -40°C to 85°C |
| LT1997HDF-3#PBF | LT1997HDF-3#TRPBF | 19973 | 14-Lead (4mm × 4mm) Plastic DFN | -40°C to 125°C |
| LT1997IMS-3#PBF | LT1997IMS-3#TRPBF | 19973 | 16-Lead Plastic MSOP | -40°C to 85°C |
| LT1997HMS-3#PBF | LT1997HMS-3#TRPBF | 19973 | 16-Lead Plastic MSOP | -40°C to 125°C |

*The temperature grade is identified by a label on the shipping container. Consult ADI Marketing for parts specified with wider operating temperature ranges. Parts ending with PBF are RoHS and WEEE compliant.

For more information on lead free part marking, go to: <http://www.linear.com/leadfree/>

For more information on tape and reel specifications, go to: <http://www.linear.com/tapeandreeel/>.

ELECTRICAL CHARACTERISTICS The ● denotes the specifications which apply over the full operating temperature range, $-40^{\circ}\text{C} < T_A < 85^{\circ}\text{C}$ for I-grade parts, $-40^{\circ}\text{C} < T_A < 125^{\circ}\text{C}$ for H-grade parts, otherwise specifications are at $T_A = 25^{\circ}\text{C}$. Difference Amplifier Configuration, $V^+ = 15\text{V}$, $V^- = -15\text{V}$, $V_{\text{CM}} = V_{\text{OUT}} = V_{\text{REF}} = V_{\text{REF1}} = V_{\text{REF2}} = 0\text{V}$. V_{CMOP} is the common mode voltage of the internal op amp.

| SYMBOL | PARAMETER | CONDITIONS | MIN | TYP | MAX | UNITS | |
|---------------------------------|---|---|-----|------------------------|----------------------------|--------------------------------|------------|
| ΔG | Gain Error | $V_{\text{OUT}} = \pm 10\text{V}$ $G = 1$ | ● | ± 0.001 | ± 0.006 ± 0.012 | % % | |
| | | $G = 3$ | ● | ± 0.001 | ± 0.015 ± 0.02 | % % | |
| | | $G = 9$ | ● | ± 0.002 | ± 0.03 ± 0.04 | % % | |
| $\Delta G/\Delta T$ | Gain Drift vs Temperature (Note 6) | $V_{\text{OUT}} = \pm 10\text{V}$ | ● | ± 0.2 | ± 1 | ppm/ $^{\circ}\text{C}$ | |
| GNL | Gain Nonlinearity | $V_{\text{OUT}} = \pm 10\text{V}$ | ● | ± 1 | ± 2 ± 3 | ppm ppm | |
| V_{OS} | Op Amp Offset Voltage (Note 9) | $V^- < V_{\text{CMOP}} < V^+ - 1.75\text{V}$ | ● | ± 20 | ± 60 ± 200 | μV μV | |
| $\Delta V_{\text{OS}}/\Delta T$ | Op Amp Offset Voltage Drift (Note 6) | $V^- < V_{\text{CMOP}} < V^+ - 1.75\text{V}$ | ● | ± 0.5 | ± 1.5 | $\mu\text{V}/^{\circ}\text{C}$ | |
| I_{B} | Op Amp Input Bias Current | $V^- + 0.25\text{V} < V_{\text{CMOP}} < V^+ - 1.75\text{V}$ | ● | -5 ± 2 -15 | 5 15 | nA nA | |
| I_{OS} | Op Amp Input Offset Current | $V^- + 0.25\text{V} < V_{\text{CMOP}} < V^+ - 1.75\text{V}$ | ● | -3 ± 0.5 -10 | 3 10 | nA nA | |
| R_{IN} | Input Impedance (Note 8) | Common Mode | | | | | |
| | | $G = 1$ | ● | 19 | 22.5 | 26 | k Ω |
| | | $G = 3$ | ● | 12.6 | 15 | 17.4 | k Ω |
| | | $G = 9$ | ● | 10.5 | 12.5 | 14.5 | k Ω |
| | | Differential | | | | | |
| | | $G = 1$ | ● | 38 | 45 | 52 | k Ω |
| CMRR | Common Mode Rejection Ratio, MS16 Package | $G = 1, V_{\text{CM}} = -28\text{V to } +26.5\text{V}$ | ● | 91 87 | 106 | dB dB | |
| | | $G = 3, V_{\text{CM}} = -15\text{V to } +17.6\text{V}$ | ● | 90 86 | 99 | dB dB | |
| | | $G = 9, V_{\text{CM}} = -15\text{V to } +14.7\text{V}$ | ● | 96 94 | 112 | dB dB | |
| | Common Mode Rejection Ratio, DF14 Package | $G = 1, V_{\text{CM}} = -28\text{V to } +26.5\text{V}$ | ● | 91 87 | 101 | dB dB | |
| | | $G = 1, V_{\text{CM}} = -90\text{V to } +90\text{V}, +\text{INB} = -\text{INB} = 0\text{V}, V_{\text{S}} = \pm 25\text{V}$ | ● | 83 80 | 94 | dB dB | |
| | | $G = 1, V_{\text{CM}} = -120\text{V to } +120\text{V}, +\text{INC} = -\text{INC} = 0\text{V}, V_{\text{S}} = \pm 25\text{V}, T_A = -40^{\circ}\text{C to } 125^{\circ}\text{C}$ | ● | 81 77 | 91 | dB dB | |
| | | $G = 1, V_{\text{CM}} = -160\text{V to } +160\text{V}, +\text{INC} = -\text{INC} = 0\text{V}, V_{\text{S}} = \pm 25\text{V}, T_A = -40^{\circ}\text{C to } 85^{\circ}\text{C}$ | ● | 81 78 | 91 | dB dB | |
| | | $G = 3, V_{\text{CM}} = -15\text{V to } +17.6\text{V}$ | ● | 90 86 | 98 | dB dB | |
| | | $G = 9, V_{\text{CM}} = -15\text{V to } +14.7\text{V}$ | ● | 96 94 | 103 | dB dB | |
| V_{CM} | Input Voltage Range (Note 7) | +INA/-INA | ● | -30 | 26.5 | V | |
| | | +INA/-INA, +INC/-INC Connected to Ground | ● | -160 | 160 | V | |
| | | +INB/-INB | ● | -15 | 17.6 | V | |
| | | +INC/-INC | ● | -15 | 14.7 | V | |

ELECTRICAL CHARACTERISTICS The ● denotes the specifications which apply over the full operating temperature range, $-40^{\circ}\text{C} < T_A < 85^{\circ}\text{C}$ for I-grade parts, $-40^{\circ}\text{C} < T_A < 125^{\circ}\text{C}$ for H-grade parts, otherwise specifications are at $T_A = 25^{\circ}\text{C}$. Difference Amplifier Configuration, $V^+ = 15\text{V}$, $V^- = -15\text{V}$, $V_{\text{CM}} = V_{\text{OUT}} = V_{\text{REF}} = V_{\text{REF1}} = V_{\text{REF2}} = 0\text{V}$. V_{CMOP} is the common mode voltage of the internal op amp.

| SYMBOL | PARAMETER | CONDITIONS | MIN | TYP | MAX | UNITS |
|-------------------|---|--|------------------|--|----------------------------|--|
| $\Delta R/R$ | Reference Divider Matching Error $\frac{\Delta R}{R} = \frac{R_{\text{REF1}} - R_{\text{REF2}}}{\left(\frac{R_{\text{REF1}} + R_{\text{REF2}}}{2}\right)}$ | Available in MS16 Package Only | ● | ± 0.001 | ± 0.006 ± 0.012 | % % |
| PSRR | Power Supply Rejection Ratio | $V_S = \pm 1.65\text{V}$ to $\pm 25\text{V}$, $V_{\text{CM}} = V_{\text{OUT}} = \text{Mid-Supply}$ (Note 9) | ● | 114 | 124 | dB |
| e_{ni} | Input Referred Noise Voltage Density | $f = 1\text{kHz}$ $G = 1$ $G = 3$ $G = 9$ | | 50 30 22 | | $\text{nV}/\sqrt{\text{Hz}}$ $\text{nV}/\sqrt{\text{Hz}}$ $\text{nV}/\sqrt{\text{Hz}}$ |
| | Input Referred Noise Voltage | $f = 0.1\text{Hz}$ to 10Hz $G = 1$ $G = 3$ $G = 9$ | | 1.4 1 0.8 | | $\mu\text{V}_{\text{P-P}}$ $\mu\text{V}_{\text{P-P}}$ $\mu\text{V}_{\text{P-P}}$ |
| V_{OL} | Output Voltage Swing Low (Referred to V^-) | No Load $I_{\text{SINK}} = 5\text{mA}$ | ● ● | 100 280 | 150 500 | mV mV |
| V_{OH} | Output Voltage Swing High (Referred to V^+) | No Load $I_{\text{SOURCE}} = 5\text{mA}$ | ● ● | 100 530 | 180 900 | mV mV |
| I_{SC} | Short-Circuit Output Current | 50Ω to V^+ 50Ω to V^- | ● ● | 10 10 | 28 30 | mA mA |
| SR | Slew Rate | $\Delta V_{\text{OUT}} = \pm 5\text{V}$ | ● | 0.45 | 0.75 | V/ μs |
| BW | Small Signal -3dB Bandwidth | $G = 1$ $G = 3$ $G = 9$ | | 1100 700 300 | | kHz kHz kHz |
| t_{S} | Settling Time | $G = 1$ 0.1%, $\Delta V_{\text{OUT}} = 10\text{V}$ 0.01%, $\Delta V_{\text{OUT}} = 10\text{V}$ $G = 3$ 0.1%, $\Delta V_{\text{OUT}} = 10\text{V}$ 0.01%, $\Delta V_{\text{OUT}} = 10\text{V}$ $G = 9$ 0.1%, $\Delta V_{\text{OUT}} = 10\text{V}$ 0.01%, $\Delta V_{\text{OUT}} = 10\text{V}$ | | 14.6 95 13.6 29 13.8 29 | | μs μs μs μs μs μs |
| V_S | Supply Voltage | | ● | 3 3.3 | 50 50 | V V |
| t_{ON} | Turn-On Time | | | 16 | | μs |
| V_{IL} | SHDN Input Logic Low (Referred to V^+) | | ● | | -2.5 | V |
| V_{IH} | SHDN Input Logic High (Referred to V^+) | | ● | -1.2 | | V |
| I_{SHDN} | SHDN Pin Current | | ● | -10 | -15 | μA |
| I_S | Supply Current | Active, $V_{\text{SHDN}} \geq V^+ - 1.2\text{V}$ Active, $V_{\text{SHDN}} \geq V^+ - 1.2\text{V}$ Shutdown, $V_{\text{SHDN}} \leq V^+ - 2.5\text{V}$ Shutdown, $V_{\text{SHDN}} \leq V^+ - 2.5\text{V}$ | ● ● ● ● | 350 350 20 | 400 600 25 70 | μA μA μA μA |

ELECTRICAL CHARACTERISTICS The ● denotes the specifications which apply over the full operating temperature range, $-40^{\circ}\text{C} < T_A < 85^{\circ}\text{C}$ for I-grade parts, $-40^{\circ}\text{C} < T_A < 125^{\circ}\text{C}$ for H-grade parts, otherwise specifications are at $T_A = 25^{\circ}\text{C}$. Difference Amplifier Configuration, $V^+ = 5\text{V}$, $V^- = 0\text{V}$, $V_{\text{CM}} = V_{\text{OUT}} = V_{\text{REF}} = V_{\text{REF1}} = V_{\text{REF2}} = \text{Mid-Supply}$. V_{CMOP} is the common mode voltage of the internal op amp.

| SYMBOL | PARAMETER | CONDITIONS | MIN | TYP | MAX | UNITS | |
|---------------------------------|---|--|-----|-------------|----------------------------|--------------------------------|------------|
| ΔG | Gain Error | $V_{\text{OUT}} = 1\text{V to } 4\text{V}$ $G = 1$ | ● | ± 0.001 | ± 0.006 ± 0.012 | % % | |
| | | $G = 3$ | ● | ± 0.001 | ± 0.015 ± 0.02 | % % | |
| | | $G = 9$ | ● | ± 0.002 | ± 0.03 ± 0.04 | % % | |
| $\Delta G/\Delta T$ | Gain Drift vs Temperature (Note 6) | $V_{\text{OUT}} = 1\text{V to } 4\text{V}$ | ● | ± 0.2 | ± 1 | ppm/ $^{\circ}\text{C}$ | |
| GNL | Gain Nonlinearity | $V_{\text{OUT}} = 1\text{V to } 4\text{V}$ | | ± 1 | | ppm | |
| V_{OS} | Op Amp Offset Voltage (Note 9) | $V^- < V_{\text{CMOP}} < V^+ - 1.75\text{V}$ | ● | ± 20 | ± 60 ± 200 | μV μV | |
| $\Delta V_{\text{OS}}/\Delta T$ | Op Amp Offset Voltage Drift (Note 6) | $V^- < V_{\text{CMOP}} < V^+ - 1.75\text{V}$ | ● | ± 0.5 | ± 1.5 | $\mu\text{V}/^{\circ}\text{C}$ | |
| I_{B} | Op Amp Input Bias Current | $V^- + 0.25\text{V} < V_{\text{CMOP}} < V^+ - 1.75\text{V}$ | ● | -5 | ± 2 | 5 | nA |
| | | | ● | -15 | | 15 | nA |
| I_{OS} | Op Amp Input Offset Current | $V^- + 0.25\text{V} < V_{\text{CMOP}} < V^+ - 1.75\text{V}$ | ● | -3 | ± 0.5 | 3 | nA |
| R_{IN} | Input Impedance (Note 8) | Common Mode | ● | 19 | 22.5 | 26 | k Ω |
| | | | ● | 12.6 | 15 | 17.4 | k Ω |
| | | | ● | 10.5 | 12.5 | 14.5 | k Ω |
| | | Differential | ● | 38 | 45 | 52 | k Ω |
| | | | ● | 12.6 | 15 | 17.4 | k Ω |
| | | | ● | 4.2 | 5 | 5.8 | k Ω |
| CMRR | Common Mode Rejection Ratio, MS16 Package | $G = 1, V_{\text{CM}} = -2.5\text{V to } +4.0\text{V}$ | ● | 90 | 100 | | dB |
| | | | ● | 88 | | | dB |
| | | $G = 3, V_{\text{CM}} = 0\text{V to } +3.5\text{V}$ | ● | 90 | 103 | | dB |
| CMRR | Common Mode Rejection Ratio, DF14 Package | $G = 1, V_{\text{CM}} = -2.5\text{V to } +4.0\text{V}$ | ● | 90 | 96 | | dB |
| | | | ● | 88 | | | dB |
| | | $G = 3, V_{\text{CM}} = 0\text{V to } +3.5\text{V}$ | ● | 90 | 101 | | dB |
| CMRR | Common Mode Rejection Ratio, DF14 Package | $G = 1, V_{\text{CM}} = -2.5\text{V to } +4.0\text{V}$ | ● | 90 | 96 | | dB |
| | | | ● | 88 | | | dB |
| | | $G = 3, V_{\text{CM}} = 0\text{V to } +3.5\text{V}$ | ● | 96 | 107 | | dB |
| $\Delta R/R$ | Reference Divider Matching Error $\frac{\Delta R}{R} = \frac{R_{\text{REF1}} - R_{\text{REF2}}}{\left(\frac{R_{\text{REF1}} + R_{\text{REF2}}}{2}\right)}$ | Available in MS16 Package Only | ● | ± 0.001 | ± 0.006 ± 0.012 | % % | |
| | | | | | | | |
| PSRR | Power Supply Rejection Ratio | $V_{\text{S}} = \pm 1.65\text{V to } \pm 25\text{V}$, $V_{\text{CM}} = V_{\text{OUT}} = \text{Mid-Supply}$ (Note 9) | ● | 114 | 124 | dB | |
| e_{ni} | Input Referred Noise Voltage Density | $f = 1\text{kHz}$ | | | | | |
| | | $G = 1$ | | 50 | | nV/ $\sqrt{\text{Hz}}$ | |
| | | $G = 3$ | | 30 | | nV/ $\sqrt{\text{Hz}}$ | |
| | | $G = 9$ | | 22 | | nV/ $\sqrt{\text{Hz}}$ | |

ELECTRICAL CHARACTERISTICS The ● denotes the specifications which apply over the full operating temperature range, $-40^{\circ}\text{C} < T_A < 85^{\circ}\text{C}$ for I-grade parts, $-40^{\circ}\text{C} < T_A < 125^{\circ}\text{C}$ for H-grade parts, otherwise specifications are at $T_A = 25^{\circ}\text{C}$. Difference Amplifier Configuration, $V^+ = 5\text{V}$, $V^- = 0\text{V}$, $V_{\text{CM}} = V_{\text{OUT}} = V_{\text{REF}} = V_{\text{REF1}} = V_{\text{REF2}} = \text{Mid-Supply}$. V_{CMOP} is the common mode voltage of the internal op amp.

| SYMBOL | PARAMETER | CONDITIONS | MIN | TYP | MAX | UNITS |
|-------------------|--|--|------------------|---------------------------------|-----------------|--|
| | Input Referred Noise Voltage | $f = 0.1\text{Hz to } 10\text{Hz}$ $G = 1$ $G = 3$ $G = 9$ | | 1.4 1 0.8 | | $\mu\text{V}_{\text{P-P}}$ $\mu\text{V}_{\text{P-P}}$ $\mu\text{V}_{\text{P-P}}$ |
| V_{OL} | Output Voltage Swing Low (Referred to V^-) | No Load $I_{\text{SINK}} = 5\text{mA}$ | ● ● | 15 280 | 50 500 | mV mV |
| V_{OH} | Output Voltage Swing High (Referred to V^+) | No Load $I_{\text{SOURCE}} = 5\text{mA}$ | ● ● | 15 450 | 50 800 | mV mV |
| I_{SC} | Short-Circuit Output Current | 50Ω to V^+ 50Ω to V^- | ● ● | 10 10 | 27 25 | mA mA |
| SR | Slew Rate | $\Delta V_{\text{OUT}} = 3\text{V}$ | ● | 0.45 | 0.75 | V/ μs |
| BW | Small signal -3dB Bandwidth | $G = 1$ $G = 3$ $G = 9$ | | 1100 700 300 | | kHz kHz kHz |
| t_{S} | Settling Time | $G = 1$ 0.1%, $\Delta V_{\text{OUT}} = 2\text{V}$ 0.01%, $\Delta V_{\text{OUT}} = 2\text{V}$ $G = 3$ 0.1%, $\Delta V_{\text{OUT}} = 2\text{V}$ 0.01%, $\Delta V_{\text{OUT}} = 2\text{V}$ $G = 9$ 0.1%, $\Delta V_{\text{OUT}} = 2\text{V}$ 0.01%, $\Delta V_{\text{OUT}} = 2\text{V}$ | | 5.4 91 6 21 7 36 | | μs μs μs μs μs μs |
| V_{S} | Supply Voltage | | ● | 3 3.3 | 50 50 | V V |
| t_{ON} | Turn-On Time | | | 22 | | μs |
| V_{IL} | $\overline{\text{SHDN}}$ Input Logic Low (Referred to V^+) | | ● | | -2.5 | V |
| V_{IH} | $\overline{\text{SHDN}}$ Input Logic High (Referred to V^+) | | ● | -1.2 | | V |
| I_{SHDN} | $\overline{\text{SHDN}}$ Pin Current | | ● | -10 | -15 | μA |
| I_{S} | Supply Current | Active, $V_{\text{SHDN}} \geq V^+ - 1.2\text{V}$ Active, $V_{\text{SHDN}} \geq V^+ - 1.2\text{V}$ Shutdown, $V_{\text{SHDN}} \leq V^+ - 2.5\text{V}$ Shutdown, $V_{\text{SHDN}} \leq V^+ - 2.5\text{V}$ | ● ● ● ● | 330 15 | 370 20 40 | μA μA μA μA |

Note 1: Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. Exposure to any Absolute Maximum Rating condition for extended periods may affect device reliability and lifetime.

Note 2: See “Common Mode Voltage Range” and “High Common Mode Voltage Difference Amplifiers” in the Applications Information section of this data sheet for other considerations when taking +INA/-INA pins to $\pm 16\text{V}$ and +INB/-INB/+INC/-INC pins to $+80\text{V}$.

Note 3: A heat sink may be required to keep the junction temperature below absolute maximum. This depends on the power supply, input voltages and the output current.

Note 4: The LT1997I-3 is guaranteed functional over the operating temperature range of -40°C to 85°C . The LT1997H-3 is guaranteed functional over the operating temperature range of -40°C to 125°C .

Note 5: The LT1997I-3 is guaranteed to meet specified performance from -40°C to 85°C . The LT1997H-3 is guaranteed to meet specified performance from -40°C to 125°C .

Note 6: This parameter is not 100% tested.

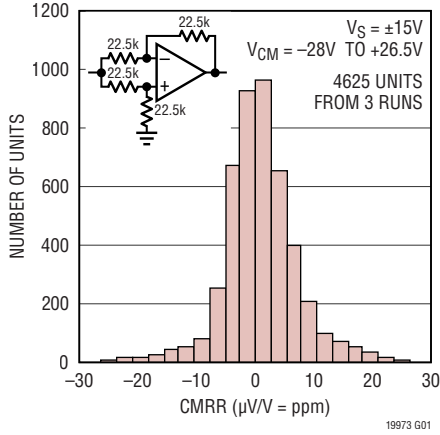
Note 7: Input voltage range is guaranteed by design and through correlation with the $\pm 15\text{V}$ CMRR test. The Input Voltage Range numbers specified in the table guarantee that the internal op amp operates in its normal operating region. The Input voltage range can be significantly higher if the internal op amp operates in its Over-The-Top® operating region. See “Common Mode Voltage Range” in the Applications Information section to determine the valid input voltage range under various operating conditions.

Note 8: Input impedance is tested by a combination of direct measurements and correlation to the CMRR and gain error tests.

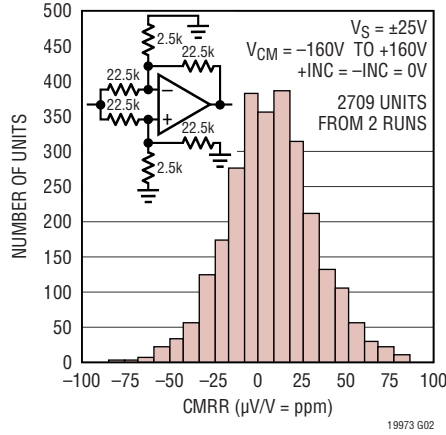
Note 9: Offset voltage, offset voltage drift and PSRR are defined as referred to the internal op amp. You can calculate output offset as follows. In the case of balanced source resistance, $V_{\text{OS,OUT}} = (V_{\text{OS}} \cdot \text{NOISEGAIN}) + (I_{\text{OS}} \cdot 22.5\text{k}) + (I_{\text{B}} \cdot 22.5\text{k} \cdot (1 - R_{\text{P}}/R_{\text{N}}))$ where R_{P} and R_{N} are the total resistance at the op amp positive and negative terminal, respectively.

TYPICAL PERFORMANCE CHARACTERISTICS $T_A = 25^\circ\text{C}$, $V_S = \pm 15\text{V}$, Difference Amplifier configuration, unless otherwise noted.

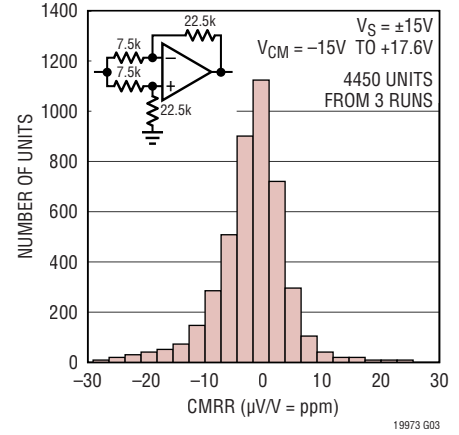
Typical Distribution of CMRR (G = 1)



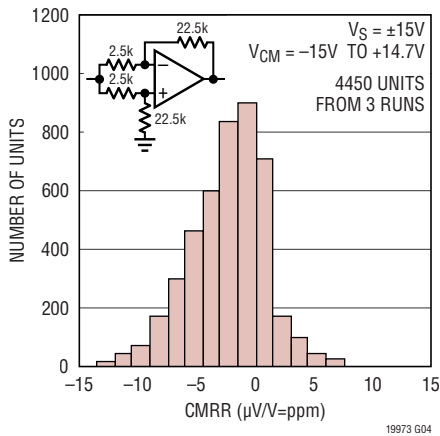
Typical Distribution of CMRR (G = 1)



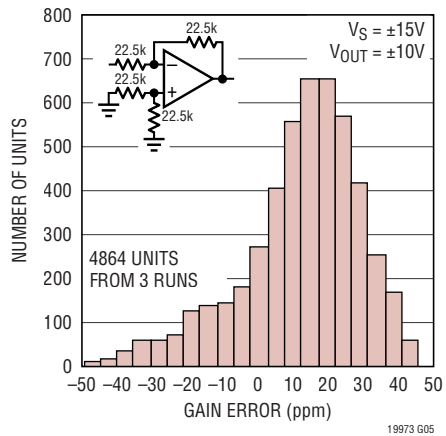
Typical Distribution of CMRR (G = 3)



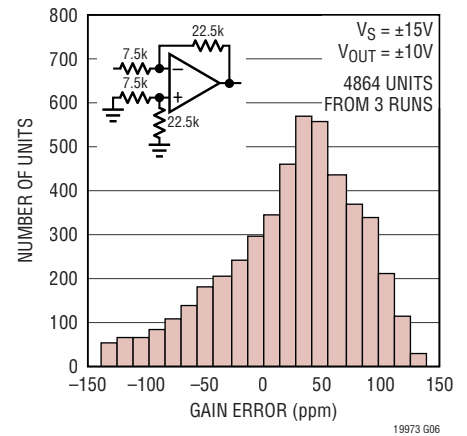
Typical Distribution of CMRR (G = 9)



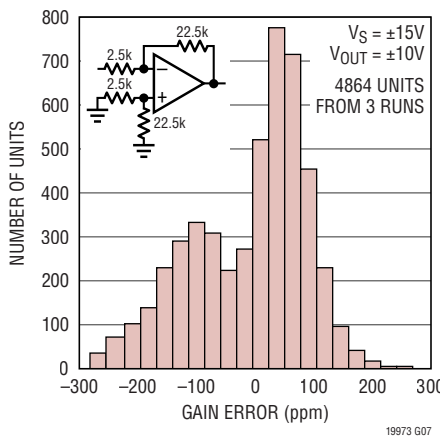
Typical Distribution of Gain Error (G = 1)



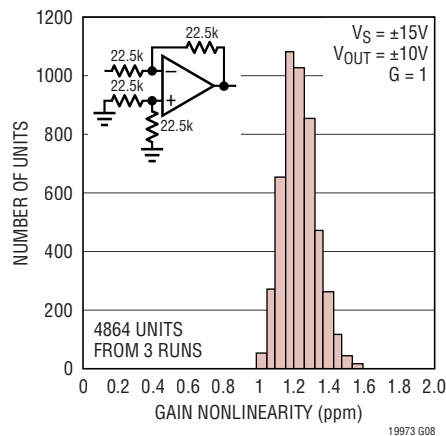
Typical Distribution of Gain Error (G = 3)



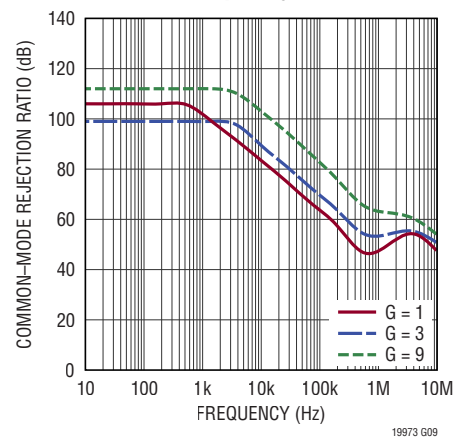
Typical Distribution of Gain Error (G = 9)



Typical Distribution of Gain Nonlinearity

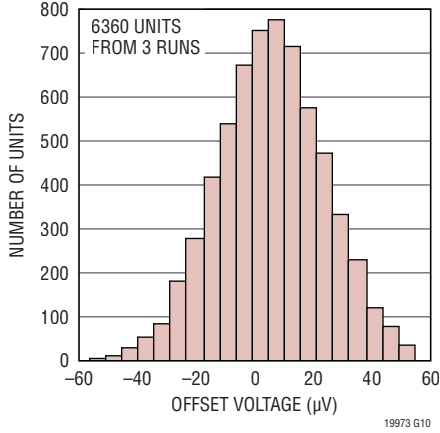


CMRR vs Frequency



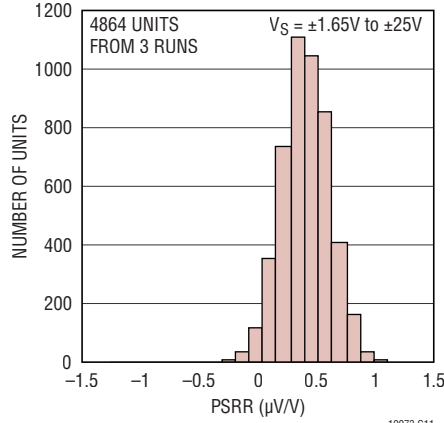
TYPICAL PERFORMANCE CHARACTERISTICS $T_A = 25^\circ\text{C}$, $V_S = \pm 15\text{V}$, Difference Amplifier configuration, unless otherwise noted.

Typical Distribution of Op Amp Offset Voltage



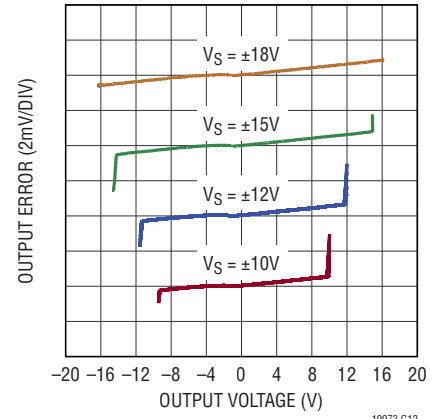
19973 G10

Typical Distribution of Op Amp PSRR



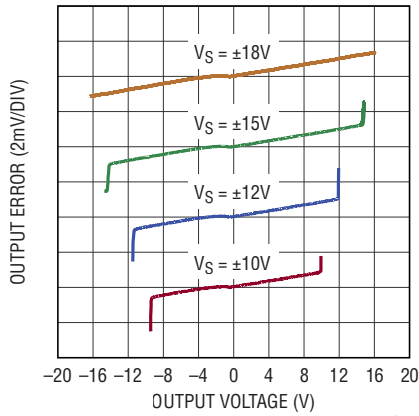
19973 G11

Typical Gain Error for $R_L = 10\text{k}\Omega$ $G = 1$ (Curves Offset for Clarity)



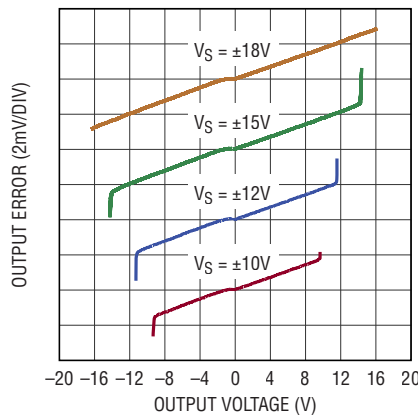
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Typical Gain Error for $R_L = 5\text{k}\Omega$ $G = 1$ (Curves Offset for Clarity)



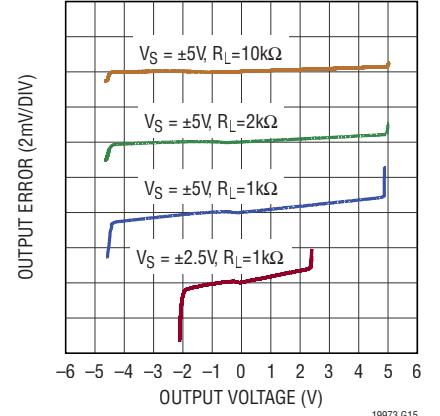
19973 G13

Typical Gain Error for $R_L = 2\text{k}\Omega$ $G = 1$ (Curves Offset for Clarity)



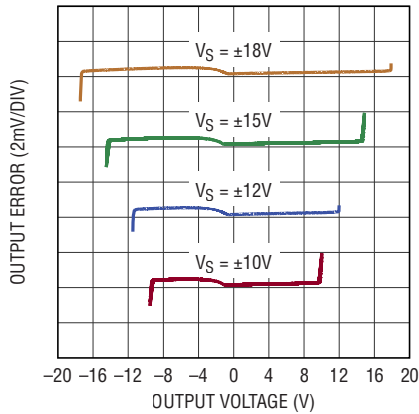
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Typical Gain Error for Low Supply Voltages, $G = 1$ (Curves Offset for Clarity)



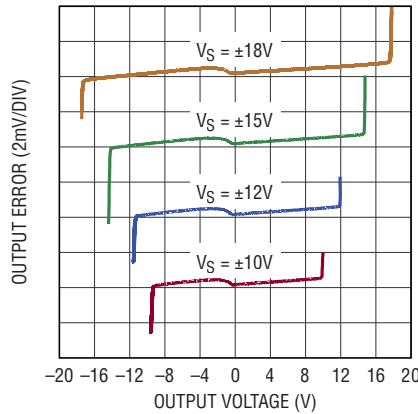
19973 G15

Typical Gain Error for $R_L = 10\text{k}\Omega$ $G = 3$ (Curves Offset for Clarity)



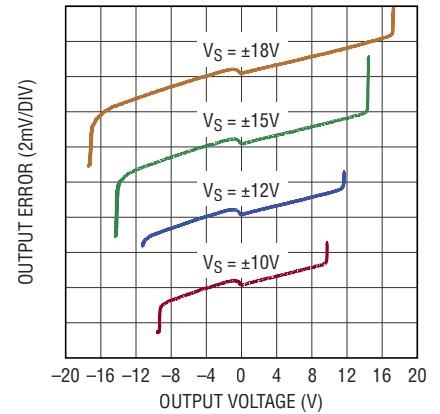
19973 G16

Typical Gain Error for $R_L = 5\text{k}\Omega$ $G = 3$ (Curves Offset for Clarity)



19973 G17

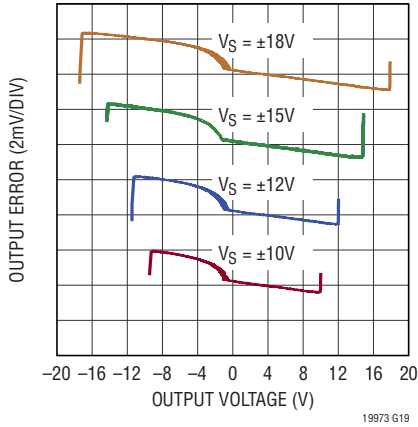
Typical Gain Error for $R_L = 2\text{k}\Omega$ $G = 3$ (Curves Offset for Clarity)



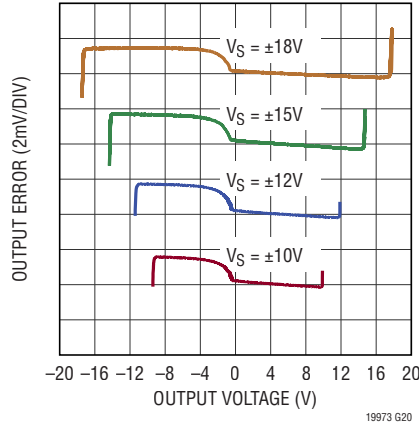
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TYPICAL PERFORMANCE CHARACTERISTICS $T_A = 25^\circ\text{C}$, $V_S = \pm 15\text{V}$, Difference Amplifier configuration, unless otherwise noted.

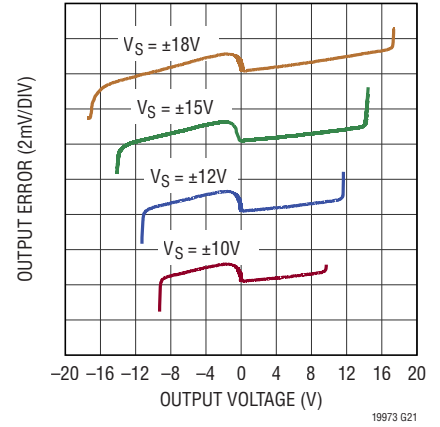
**Typical Gain Error for $R_L = 10\text{k}\Omega$
 $G = 9$ (Curves Offset for Clarity)**



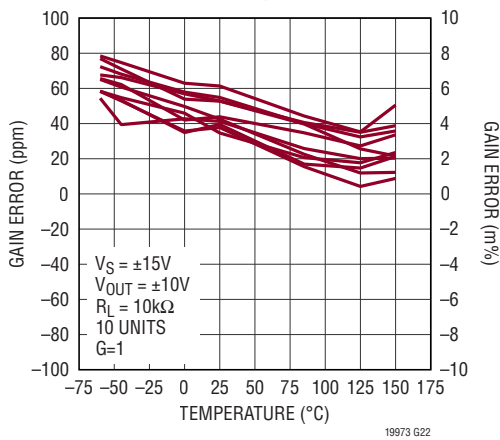
**Typical Gain Error for $R_L = 5\text{k}\Omega$
 $G = 9$ (Curves Offset for Clarity)**



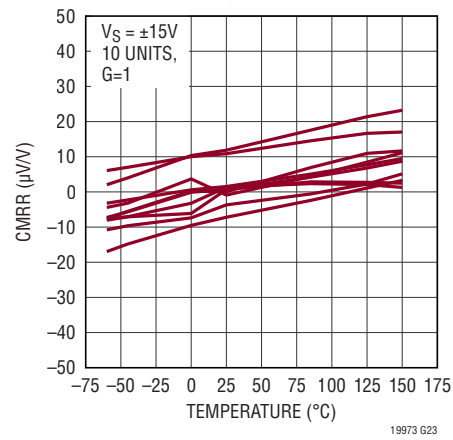
**Typical Gain Error for $R_L = 2\text{k}\Omega$
 $G = 9$ (Curves Offset for Clarity)**



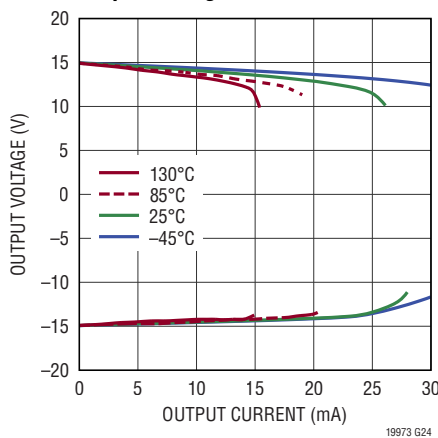
Gain Error vs Temperature



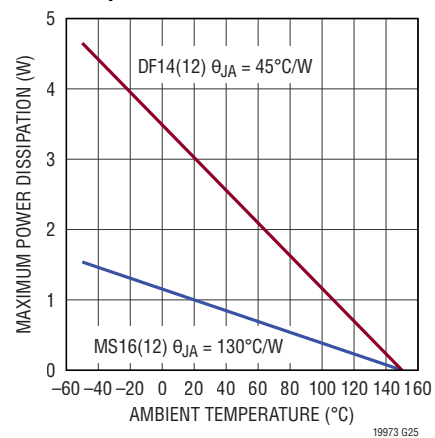
CMRR vs Temperature



Output Voltage vs Load Current

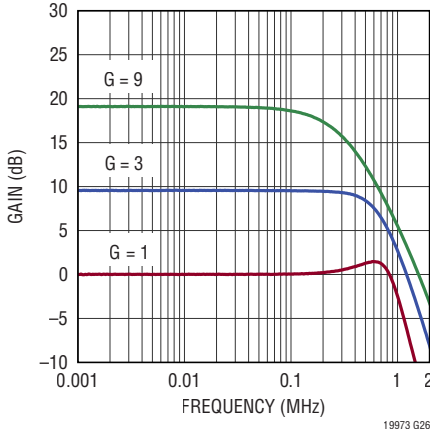


Maximum Power Dissipation vs Temperature

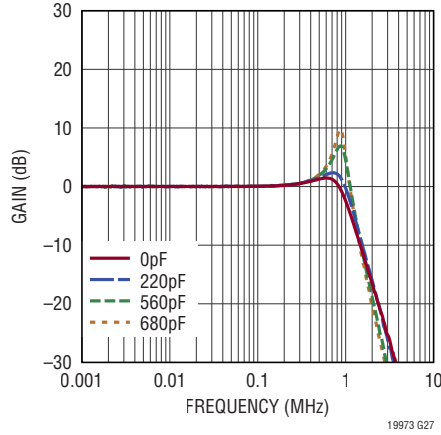


TYPICAL PERFORMANCE CHARACTERISTICS $T_A = 25^\circ\text{C}$, $V_S = \pm 15\text{V}$, Difference Amplifier configuration, unless otherwise noted.

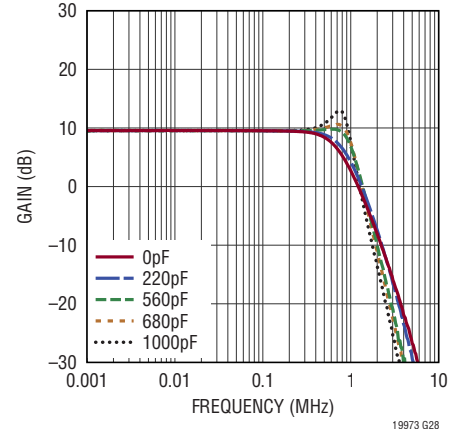
Gain vs Frequency



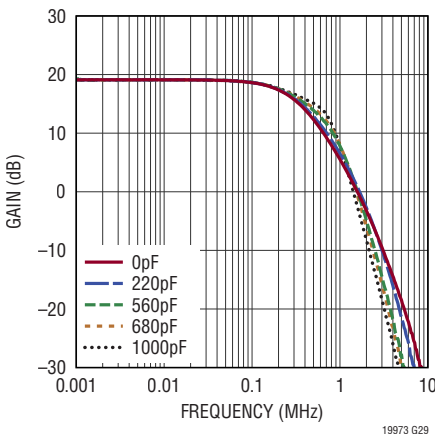
Frequency Response vs Capacitive Load (G = 1)



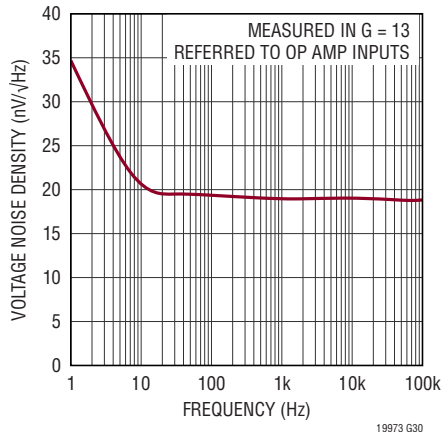
Frequency Response vs Capacitive Load (G = 3)



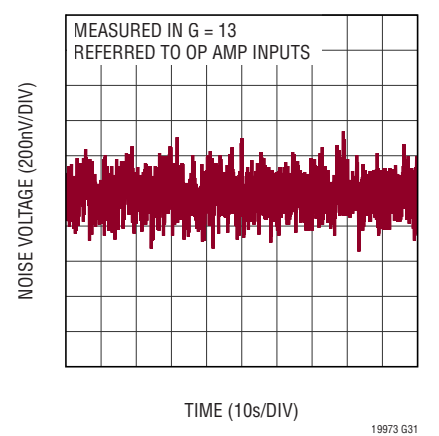
Frequency Response vs Capacitive Load (G = 9)



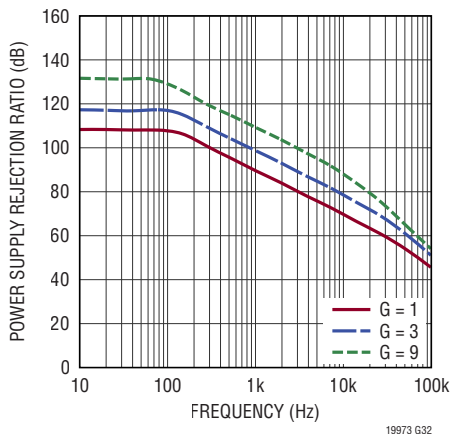
Op Amp Noise Density vs Frequency



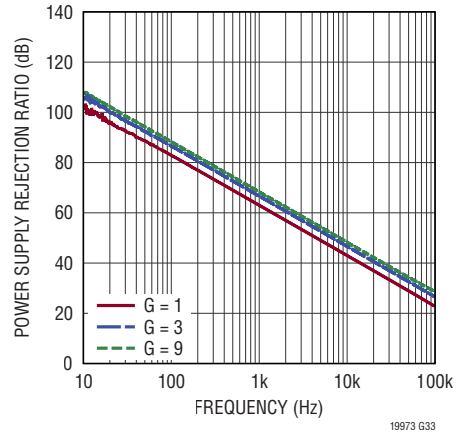
0.1Hz to 10Hz Noise



Positive PSRR vs Frequency

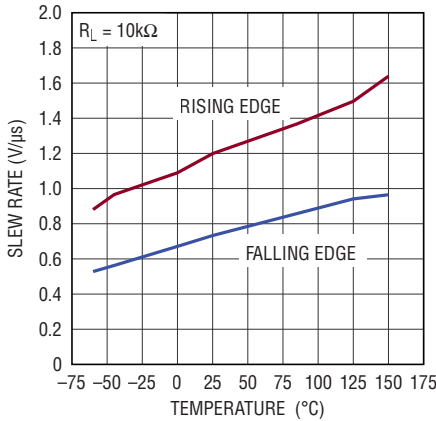


Negative PSRR vs Frequency



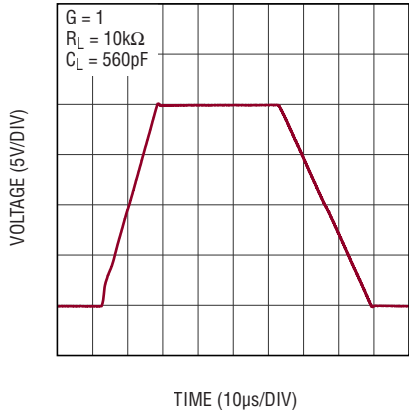
TYPICAL PERFORMANCE CHARACTERISTICS $T_A = 25^\circ\text{C}$, $V_S = \pm 15\text{V}$, Difference Amplifier configuration, unless otherwise noted.

Slew Rate vs Temperature



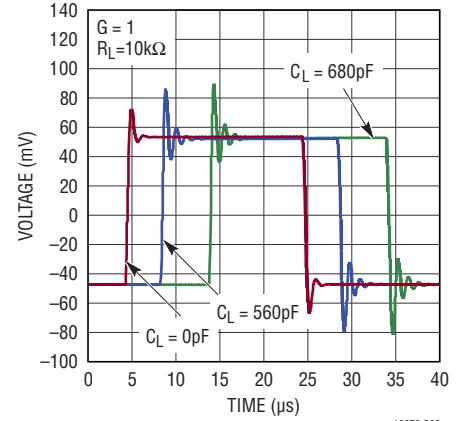
19973 G34

Large-Signal Step Response



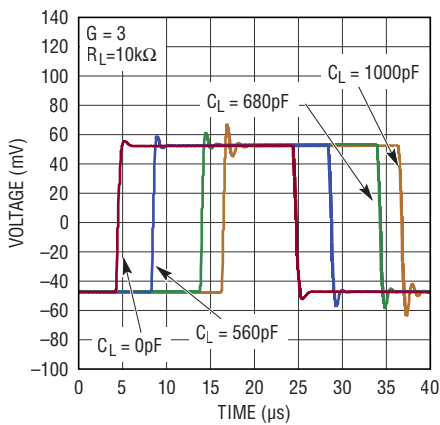
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Small-Signal Step Response



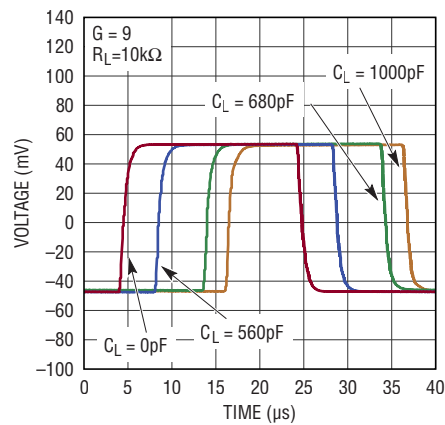
19973 G36

Small-Signal Step Response



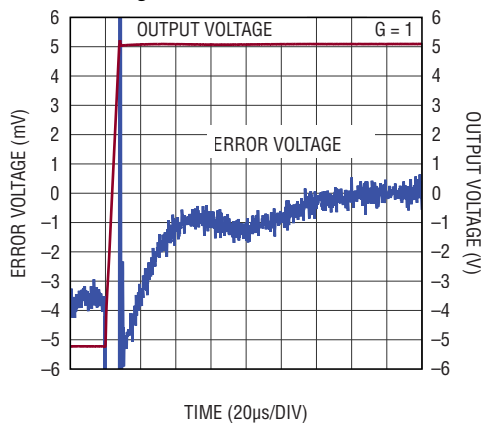
19973 G37

Small-Signal Step Response



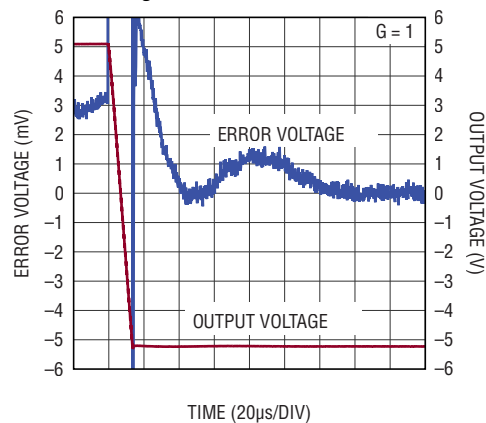
19973 G38

Settling Time



19973 G39

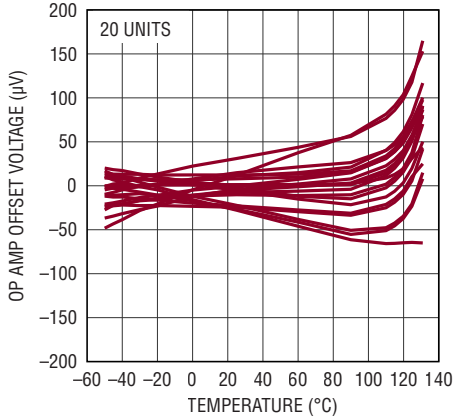
Settling Time



19973 G40

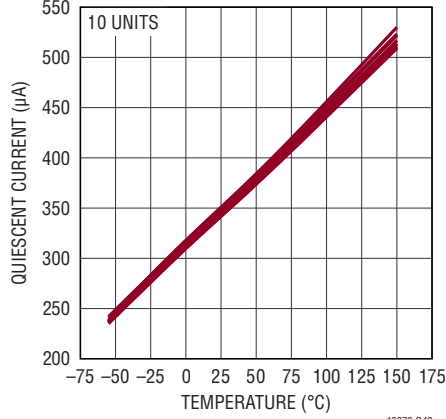
TYPICAL PERFORMANCE CHARACTERISTICS $T_A = 25^\circ\text{C}$, $V_S = \pm 15\text{V}$, Difference Amplifier configuration, unless otherwise noted.

Op Amp Offset Voltage vs Temperature



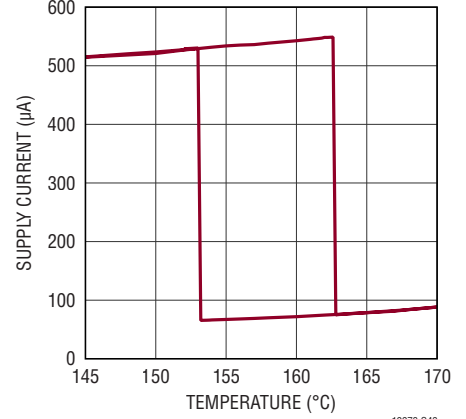
19973 G41

Quiescent Current vs Temperature



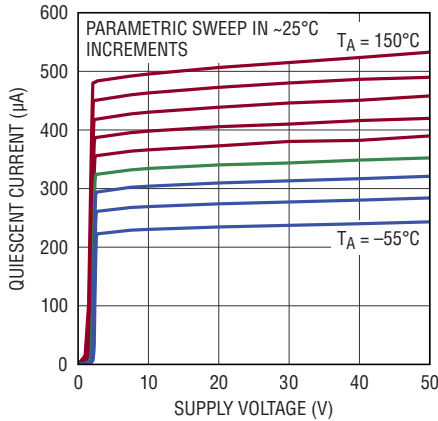
19973 G42

Thermal Shutdown vs Hysteresis



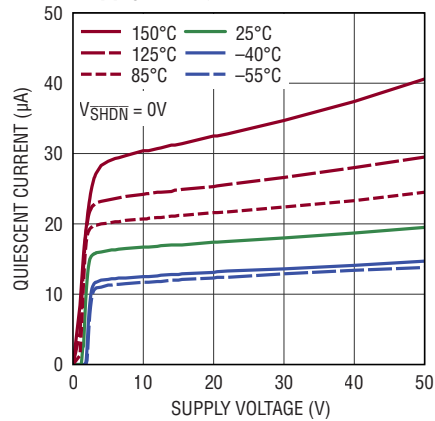
19973 G43

Quiescent Current vs Supply Voltage



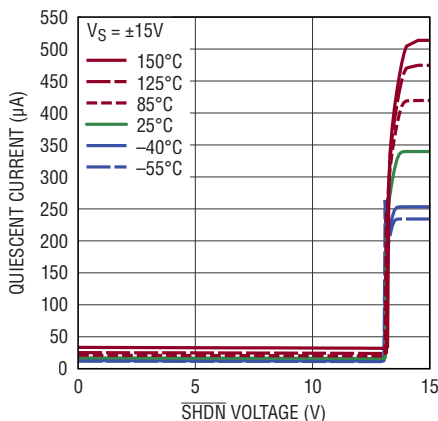
19973 G44

Shutdown Quiescent Current vs Supply Voltage



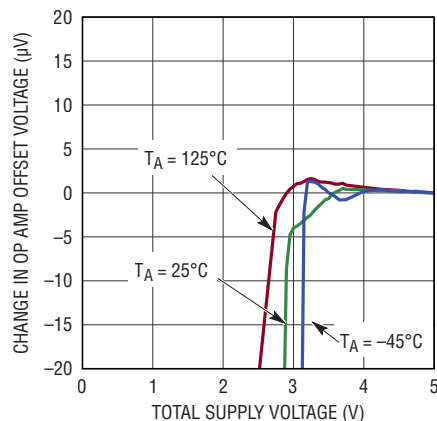
19973 G45

Quiescent Current vs SHDN Voltage



19973 G46

Minimum Supply Voltage



19973 G47

PIN FUNCTIONS (DFN/MSOP)

V⁺ (Pin 9/Pin 11): Positive Supply Pin.

V⁻ (EXPOSED PAD Pin 15/Pin 8): Negative Supply Pin.

OUT (Pin 8/Pin 9): Output Pin.

+INA (Pin 1/Pin 1): Noninverting Gain-of-1 Input Pin. Connects a 22.5k internal resistor to the internal op amp's noninverting input.

+INB (Pin 3/Pin 3): Noninverting Gain-of-3 Input Pin. Connects a 7.5k internal resistor to the internal op amp's noninverting input.

+INC (Pin 5/Pin 5): Noninverting Gain-of-9 Input Pin. Connects a 2.5k internal resistor to the internal op amp's noninverting input.

-INA (Pin 14/Pin 16): Inverting Gain-of-1 input Pin. Connects a 22.5k internal resistor to the internal op amp's inverting input.

-INB (Pin 12/Pin 14): Inverting Gain-of-3 input Pin. Connects a 7.5k internal resistor to the internal op amp's inverting input.

-INC (Pin 10/Pin 12): Inverting Gain-of-9 input Pin. Connects a 2.5k internal resistor to the internal op amp's inverting input.

REF (Pin 7/NA): Reference Input Pin. Sets the output level when the difference between the inputs is zero.

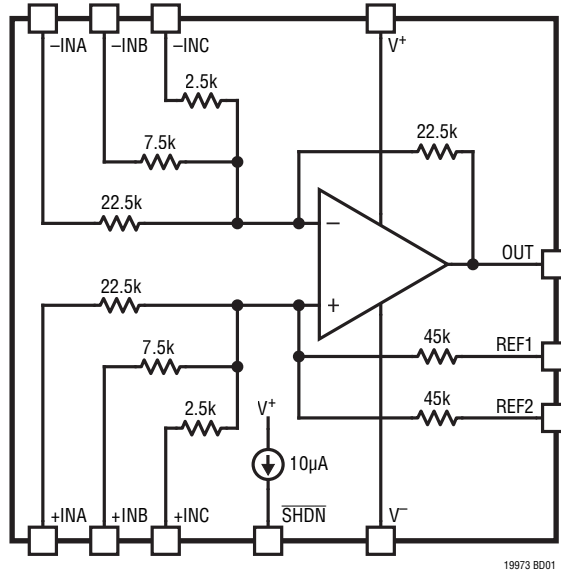
REF1 (NA/Pin 6): Reference 1 Input Pin. With REF2, sets the output level when the difference between the inputs is zero.

REF2 (NA/Pin 7): Reference 2 Input Pin. With REF1, sets the output level when the difference between the inputs is zero.

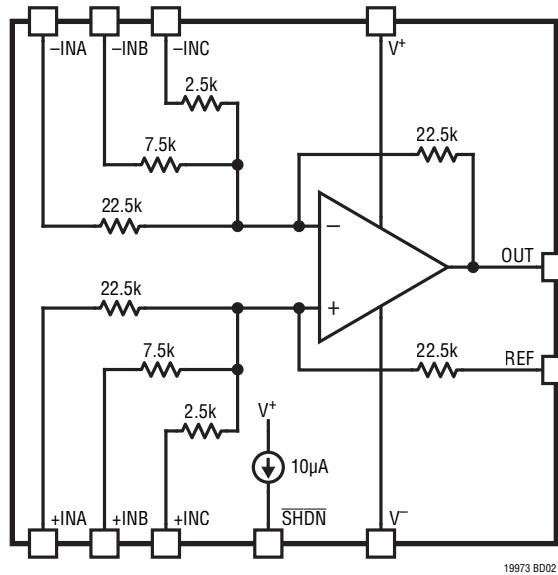
SHDN (Pin 6/Pin 10): Shutdown Pin. Amplifier is active when this pin is tied to V⁺ or left floating. Pulling the pin >2.5V below V⁺ causes the amplifier to enter a low power state.

BLOCK DIAGRAM

MSOP



DFN



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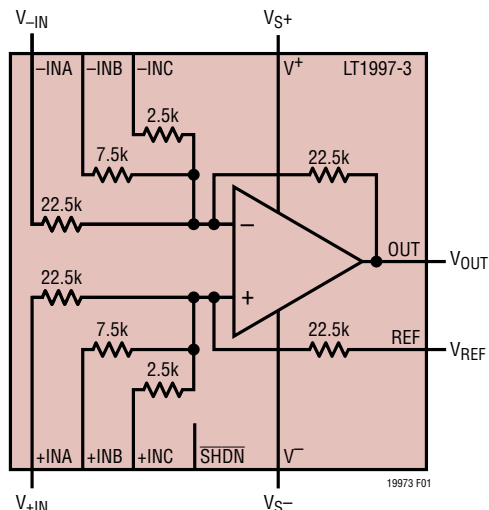


Figure 1. Difference Amplifier with Dual-Supply Operation (Gain = 1)

Introduction

The LT1997-3 is a precision, high voltage general purpose op amp combined with a highly-matched resistor network. It can easily be configured into many different classical gain circuits without adding external components. The several pages of simple circuits in this data sheet demonstrate how easy the LT1997-3 is to use. It can be configured into a difference amplifier (Figure 1), as well as into inverting (Figure 7) and noninverting (Figure 3) single ended amplifiers. The LT1997-3 provides the resistors and op amp together in a small package in order to save board space and reduce complexity. Highly accurate measurement circuits can be easily constructed with the LT1997-3. The circuits can be tailored to specific measurement applications.

Common Mode Voltage Range

The common mode voltage range of the LT1997-3 is set by the voltage range allowed on the LT1997-3's input pins and by the input voltage range of the internal op amp.

The internal op amp of LT1997-3 has 2 operating regions: a) if the common-mode voltage at the inputs of the internal

op amp (V_{CMOP}) is between V^- and $V^+ - 1.75V$, the op amp operates in its normal region; b) If V_{CMOP} is between $V^+ - 1.75V$ and $V^- + 76V$, the op amp continues to operate, but in its Over-The-Top (OTT) region with degraded performance (see Over-The-Top Operation section of this data sheet for more detail).

The LT1997-3 will not operate correctly if the common-mode voltage at the inputs of the internal op amp (V_{CMOP}) is below V^- , but the part will not be damaged as long as V_{CMOP} is greater than $V^- - 25V$ and the junction temperature of the LT1997-3 does not exceed $150^{\circ}C$.

The allowed voltage range on LT1997-3's input pins are as follows: The voltages at +INA and -INA input pins should never be higher than $V^- + 160V$ or lower than $V^- - 160V$ under any circumstances; The voltages at +INB, -INB, +INC and -INC input pins should not go below $V^- - 0.3V$ or above $V^- + 80V$.

The common-mode voltage at the inputs of the internal op amp (V_{CMOP}) is determined by the voltages on pins +INA, +INB, +INC and REF (see the "Calculating Input Voltage Range" section). This condition is true provided that the internal op amp's output is not clipped and feedback maintains the internal op amp's inputs at the same voltage.

In addition to the limits mentioned above, the common mode input voltage of the amplifier should be chosen so that the input resistors do not dissipate too much power. The power dissipated in a 22.5k resistor must be less than 1.5W. It must be less than 0.5W for the 7.5k resistor and less than 0.165W for the 2.5k resistor. For most applications, the pin voltage limitations will be reached before the resistor power limitation is reached.

Calculating Input Voltage Range

Figure 2 shows the LT1997-3 in the generalized case of a difference amplifier, with the inputs shorted for the common mode calculation. The values of R_F and R_G are dictated by how the positive inputs and REF pin are connected.

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By superposition we can write:

$$V_{CMOP} = V_{EXT} \cdot \frac{R_F}{R_F + R_G} + V_{REF} \cdot \frac{R_G}{R_F + R_G}$$

Or, solving for V_{EXT} :

$$V_{EXT} = V_{CMOP} \cdot \left(1 + \frac{R_G}{R_F}\right) - V_{REF} \cdot \frac{R_G}{R_F}$$

But valid V_{CMOP} voltages are limited to $V_{S+} - 1.75V$ ($V_{S-} + 76V$ OTT) on the high side and V_{S-} on the low side, so:

$$MAX V_{EXT} = (V_{S+} - 1.75) \cdot \left(1 + \frac{R_G}{R_F}\right) - V_{REF} \cdot \frac{R_G}{R_F}$$

and:

$$MIN V_{EXT} = (V_{S-}) \cdot \left(1 + \frac{R_G}{R_F}\right) - V_{REF} \cdot \frac{R_G}{R_F}$$

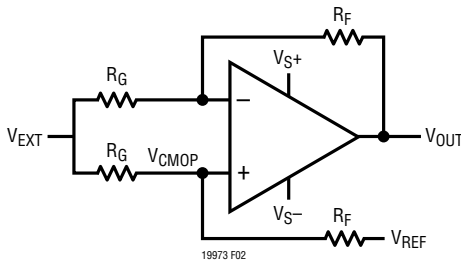


Figure 2. Calculating the Common Mode Input Voltage Range

Exceeding the $MAX V_{EXT}$ limit will cause the amplifier to transition into the Over-The-Top region. The maximum input voltage for the Over-The-Top region is:

$$MAX V_{EXTOTT} = (V_{S-} + 76) \cdot \left(1 + \frac{R_G}{R_F}\right) - V_{REF} \cdot \frac{R_G}{R_F}$$

Keep in mind that the above MAX and MIN values for input voltage range should not exceed the allowed voltage range specified earlier for LT1997-3's input pins.

The negative inputs are not limited by the internal op amp common mode range (V_{CMOP}) because they do not affect it.

They are limited by the output swing of the amplifier (and obviously by the allowed voltage range for the input pins).

Over-The-Top Operation

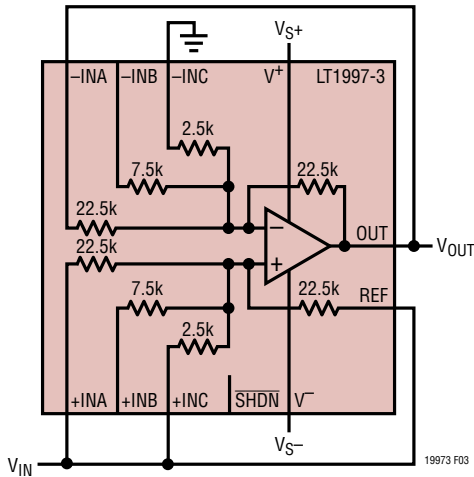
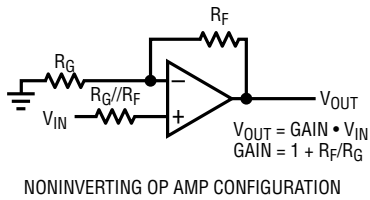
When the input common mode voltage of the internal op amp (V_{CMOP}) in the LT1997-3 is biased near or above the V^+ supply, the op amp is operating in the Over-The-Top (OTT) region. The op amp continues to operate with an input common mode voltage of up to 76V above V^- (regardless of the positive power supply voltage V^+), but its performance is degraded. The op amp's input bias currents change from under $\pm 2nA$ to $14\mu A$. The op amp's input offset current rises to $\pm 50nA$, which adds $\pm 1.1mV$ to the output offset voltage.

In addition, when operating in the Over-The-Top region, the differential input impedance decreases from $1M\Omega$ in normal operation to approximately $3.7k\Omega$ in Over-The-Top operation. This resistance appears across the summing nodes of the internal op amp and boosts noise and offset while decreasing speed. Noise and offset will increase by between 75% and 450% depending on the gain setting. The bandwidth will be reduced by 2X to 5.5X. For more detail on Over-The-Top operation, consult the LT6015 data sheet.

The Classical Noninverting Amplifier: High Input Z

A common op amp configuration enabled by the LT1997-3 is the noninverting amplifier. Figure 3 shows the textbook representation of the circuit on the top. The LT1997-3 is shown on the bottom configured in a precision gain of 5.5. One of the benefits of the noninverting op amp configuration is that the input impedance is extremely high. The LT1997-3 maintains this benefit. A large number of gains can be achieved with the LT1997-3 in the noninverting configuration. The complete list of such Hi-Z input noninverting gain configuration is shown in Table 1. Many of these are also represented in Figure 4 in schematic form. Note that the positive inputs are connected such that the source impedance seen by the positive and negative inputs of the internal op amp are equal. This minimizes the offset voltage due to the input bias current of the op amp. The noise gain and amplifier's gain in the noninverting configuration are identical.

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NONINVERTING OP AMP CONFIGURATION
 IMPLEMENTED WITH THE LT1997-3, $R_F = 11.25k$, $R_G = 2.5k$, GAIN = 5.5
 GAIN IS ACHIEVED BY GROUNDING, FLOATING OR FEEDING BACK
 THE AVAILABLE RESISTORS TO ARRIVE AT THE DESIRED R_F AND R_G

Figure 3. The LT1997-3 Configured as a Noninverting Op Amp

Table 1. Configuring the Negative Pins for Noninverting Gains. The Positive Inputs Are Driven as Shown in the Examples in Figure 4

| Gain | Negative Input Connections | | |
|-------|----------------------------|-----------|-----------|
| | -INA | -INB | -INC |
| 1 | V_{OUT} | V_{OUT} | V_{OUT} |
| 1.077 | GND | V_{OUT} | V_{OUT} |
| 1.1 | GND | OPEN | V_{OUT} |
| 1.25 | GND | V_{OUT} | OPEN |
| 1.273 | V_{OUT} | GND | V_{OUT} |
| 1.3 | OPEN | GND | V_{OUT} |
| 1.4 | GND | GND | V_{OUT} |
| 2 | GND | OPEN | OPEN |
| 2.5 | V_{OUT} | GND | OPEN |
| 2.8 | V_{OUT} | V_{OUT} | GND |
| 3.25 | OPEN | V_{OUT} | GND |
| 3.5 | GND | V_{OUT} | GND |
| 4 | OPEN | GND | OPEN |
| 5 | GND | GND | OPEN |
| 5.5 | V_{OUT} | OPEN | GND |
| 7 | V_{OUT} | GND | GND |
| 10 | OPEN | OPEN | GND |
| 11 | GND | OPEN | GND |
| 13 | OPEN | GND | GND |
| 14 | GND | GND | GND |

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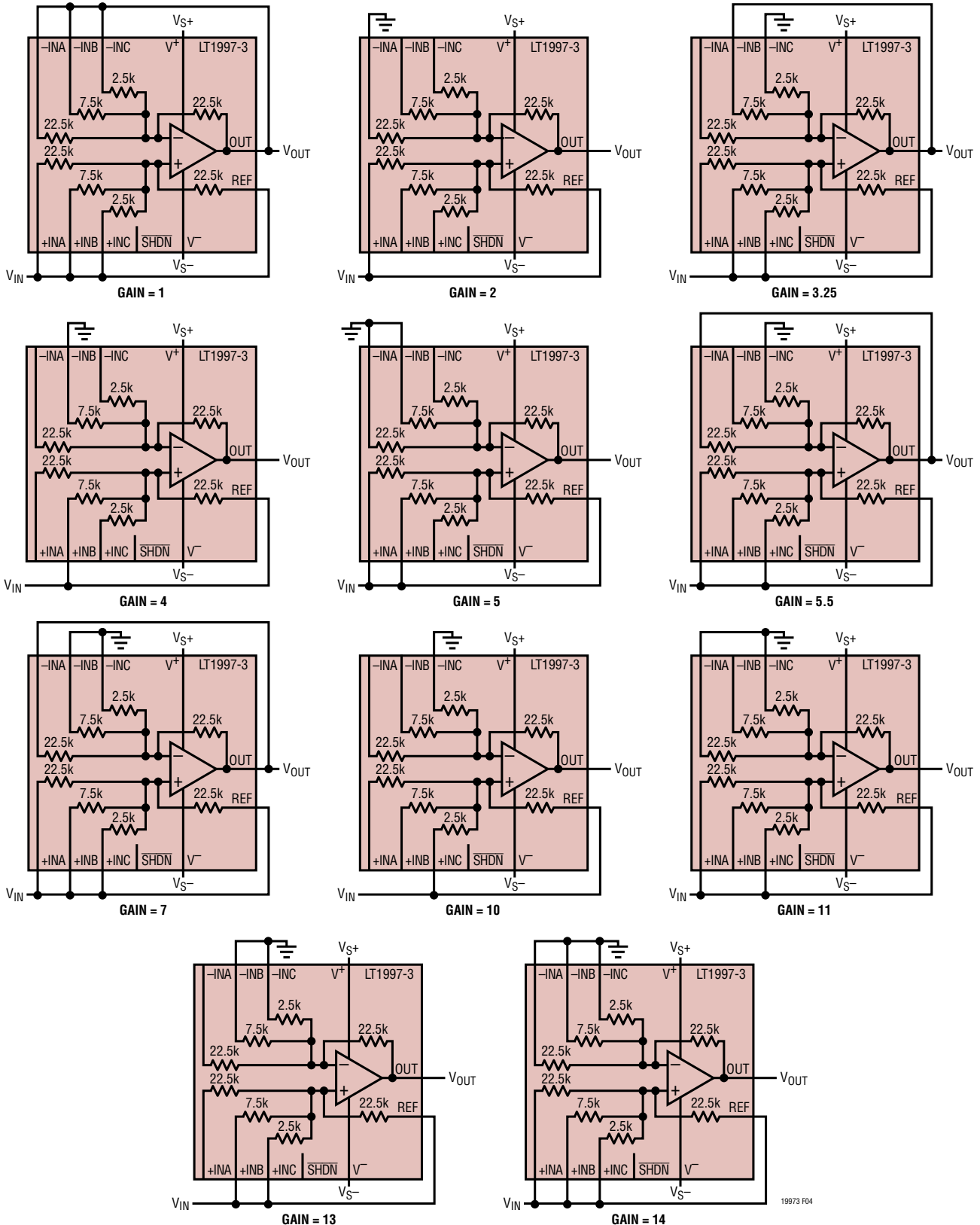


Figure 4. Some Implementations of Classical Noninverting Gains Using the LT1997-3. High Input Z is Maintained

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Attenuation

The positive input resistors can be configured to attenuate the input signal (Figure 5). This allows a trade-off to be made between input range and precision. Attenuating the input can prevent the op amp from entering the less precise Over-the-Top operating region at the cost of decreasing the output signal. The four positive resistors (R_{+INA} , R_{+INB} , R_{+INC} , R_{REF}) can be arranged to make many precise input attenuators. These are shown in Table 2.

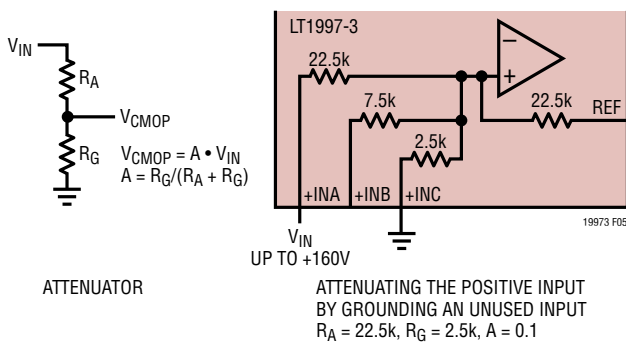


Figure 5. The Input of the LT1997-3 Can Be Attenuated to Increase the Usable Input Range. The +INA Input Can Be Taken to ±160V.

The attenuations and noninverting gains are set independently and can be combined to produce even more gain options. 346 unique gains between 0.0714 and 14 (Figure 6) can be realized. When using the positive side resistors as an attenuator, the benefit of canceling input bias current effects on offset voltage reduces. The impedance seen by the two op amp input nodes will not be identical.

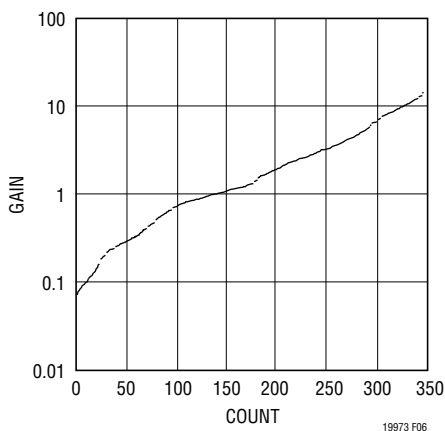


Figure 6. Many Unique Gains Can Be Achieved by Combining Attenuation with Noninverting Gain

Table 2. Configuring the Positive Pins for Various Attenuations

| Gain | Positive Input Connections | | | |
|--------|----------------------------|-----------------|-----------------|-----------------|
| | +INA | +INB | +INC | REF |
| 0.0714 | V _{IN} | GND | GND | GND |
| 0.0769 | V _{IN} | GND | GND | OPEN |
| 0.0909 | V _{IN} | OPEN | GND | GND |
| 0.1 | V _{IN} | OPEN | GND | OPEN |
| 0.143 | V _{IN} | GND | GND | V _{IN} |
| 0.182 | V _{IN} | OPEN | GND | V _{IN} |
| 0.2 | V _{IN} | GND | OPEN | GND |
| 0.214 | GND | V _{IN} | GND | GND |
| 0.231 | OPEN | V _{IN} | GND | GND |
| 0.25 | V _{IN} | GND | OPEN | OPEN |
| 0.286 | V _{IN} | V _{IN} | GND | GND |
| 0.308 | V _{IN} | V _{IN} | GND | OPEN |
| 0.357 | V _{IN} | V _{IN} | GND | V _{IN} |
| 0.4 | V _{IN} | GND | OPEN | V _{IN} |
| 0.5 | V _{IN} | OPEN | OPEN | GND |
| 0.6 | GND | V _{IN} | OPEN | GND |
| 0.643 | GND | GND | V _{IN} | GND |
| 0.692 | OPEN | GND | V _{IN} | GND |
| 0.714 | V _{IN} | GND | V _{IN} | GND |
| 0.75 | OPEN | V _{IN} | OPEN | GND |
| 0.769 | V _{IN} | GND | V _{IN} | OPEN |
| 0.786 | V _{IN} | GND | V _{IN} | V _{IN} |
| 0.8 | V _{IN} | V _{IN} | OPEN | GND |
| 0.818 | GND | OPEN | V _{IN} | GND |
| 0.857 | GND | V _{IN} | V _{IN} | GND |
| 0.9 | OPEN | OPEN | V _{IN} | GND |
| 0.909 | V _{IN} | OPEN | V _{IN} | GND |
| 0.923 | OPEN | V _{IN} | V _{IN} | GND |
| 0.929 | V _{IN} | V _{IN} | V _{IN} | GND |
| 1 | V _{IN} | V _{IN} | V _{IN} | V _{IN} |

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The Inverting Configuration

The inverting amplifier, shown in Figure 7, is another classical op amp configuration. The circuit is actually identical to the noninverting amplifier of Figure 3, except that V_{IN} and GND have been swapped. The list of available gains is shown in Table 3, and some of the circuits are shown in Figure 8. Noise gain is $1+|Gain|$, as is the usual case for inverting amplifiers. For the best DC precision, match the source impedances seen by the op amp inputs.

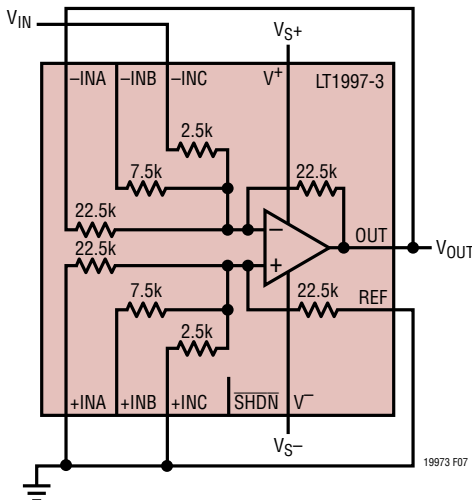
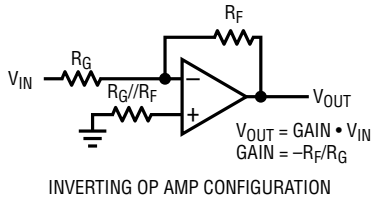


Table 3. Configuring the Negative Pins for Inverting Gains

| Gain | Negative Input Connections | | |
|--------|----------------------------|-----------|-----------|
| | -INA | -INB | -INC |
| -0.077 | V_{IN} | V_{OUT} | V_{OUT} |
| -0.1 | V_{IN} | OPEN | V_{OUT} |
| -0.25 | V_{IN} | V_{OUT} | OPEN |
| -0.273 | V_{OUT} | V_{IN} | V_{OUT} |
| -0.3 | OPEN | V_{IN} | V_{OUT} |
| -0.4 | V_{IN} | V_{IN} | V_{OUT} |
| -1 | V_{IN} | OPEN | OPEN |
| -1.5 | V_{OUT} | V_{IN} | OPEN |
| -1.8 | V_{OUT} | V_{OUT} | V_{IN} |
| -2.25 | OPEN | V_{OUT} | V_{IN} |
| -2.5 | V_{IN} | V_{OUT} | V_{IN} |
| -3 | OPEN | V_{IN} | OPEN |
| -4 | V_{IN} | V_{IN} | OPEN |
| -4.5 | V_{OUT} | OPEN | V_{IN} |
| -6 | V_{OUT} | V_{IN} | V_{IN} |
| -9 | OPEN | OPEN | V_{IN} |
| -10 | V_{IN} | OPEN | V_{IN} |
| -12 | OPEN | V_{IN} | V_{IN} |
| -13 | V_{IN} | V_{IN} | V_{IN} |

Figure 7. The LT1997-3 Configured as an Inverting Op Amp

APPLICATIONS INFORMATION

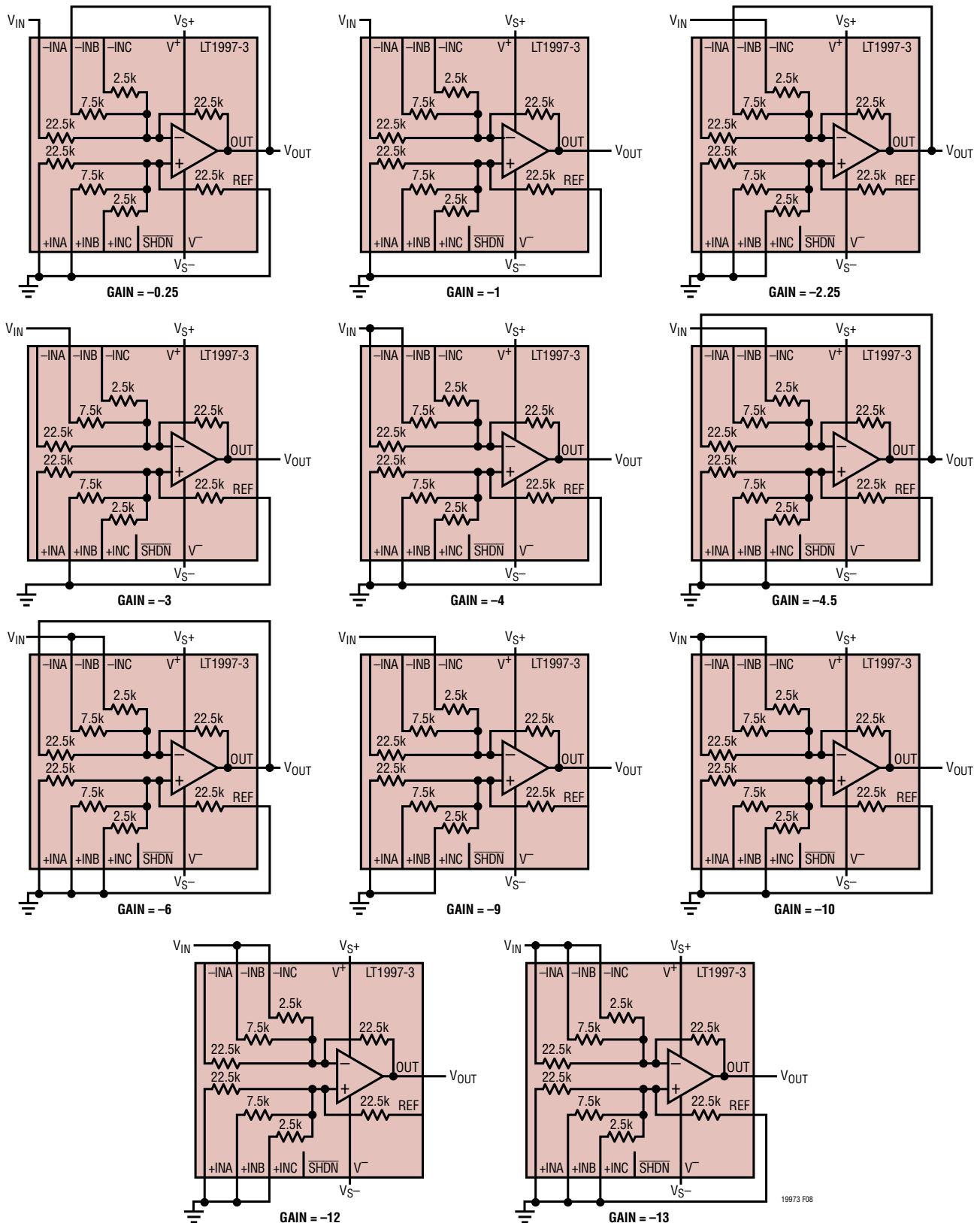


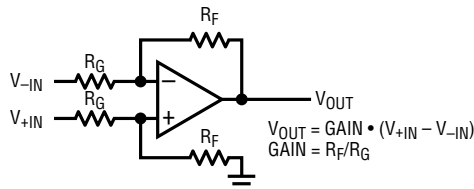
Figure 8. Inverting Gains with Input Impedance that Varies from 1.73kΩ (Gain = -13) to 22.5kΩ (Gain = -1)

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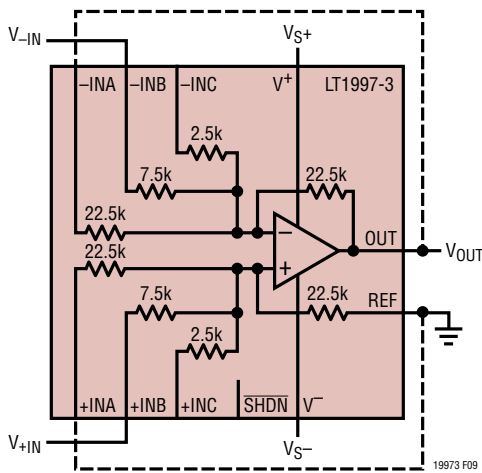
APPLICATIONS INFORMATION

Difference Amplifiers

The LT1997-3 is ideally suited to be used as a difference amplifier. Figure 9 shows the basic 4-resistor difference amplifier and the LT1997-3. A difference gain of 3 is shown, but can be altered by additional dashed connections. By connecting the 22.5k resistors in parallel, the gain is reduced by a factor of 2. Of course there are many possible gains. Table 4 shows the difference gains and how they are achieved. Note that, as for inverting amplifiers, the noise gain is equal to the signal gain plus 1.



DIFFERENCE AMPLIFIER CONFIGURATION



DIFFERENCE AMPLIFIER CONFIGURATION
 IMPLEMENTED WITH THE LT1997-3, $R_F = 22.5k$, $R_G = 7.5k$, $GAIN = 3$
 ADDING THE DASHED CONNECTIONS CONNECT THE
 TWO 22.5k RESISTORS IN PARALLEL, SO R_F IS REDUCED TO 11.25k.
 THE GAIN BECOMES $11.25k/7.5k = 1.5$

Figure 9. The LT1997-3 Configured as a Difference Amplifier. Gain Is Set by Connecting the Correct Resistors or Combinations of Resistors. Gain of 3 Is Shown, with Dashed Lines Modifying It to a Gain of 1.5

The Common Mode Voltage at the inputs of the internal op amp (V_{CMOP}) is set by the voltages at pins +INA, +INB, +INC and REF.

Table 4. Difference Amplifier Gains

| Gain | V _{+IN} | V _{-IN} | OUT | GND (REF) |
|-------|---------------------|---------------------|------------|------------|
| 0.077 | +INA | -INA | -INB, -INC | +INB, +INC |
| 0.1 | +INA | -INA | -INC | +INC |
| 0.25 | +INA | -INA | -INB | +INB |
| 0.273 | +INB | -INB | -INA, -INC | +INA, +INC |
| 0.3 | +INB | -INB | -INC | +INC |
| 0.4 | +INA, +INB | -INA, -INB | -INC | +INC |
| 1 | +INA | -INA | | |
| 1.5 | +INB | -INB | -INA | +INA |
| 1.8 | +INC | -INC | -INA, -INB | +INA, +INB |
| 2.25 | +INC | -INC | -INB | +INB |
| 2.5 | +INA, +INC | -INA, -INC | -INB | +INB |
| 3 | +INB | -INB | | |
| 4 | +INA, +INB | -INA, -INB | | |
| 4.5 | +INC | -INC | -INA | +INA |
| 6 | +INB, +INC | -INB, -INC | -INA | +INA |
| 9 | +INC | -INC | | |
| 10 | +INA, +INC | -INA, -INC | | |
| 12 | +INB, +INC | -INB, -INC | | |
| 13 | +INA, +INB, +INC | -INA, -INB, -INC | | |

APPLICATIONS INFORMATION

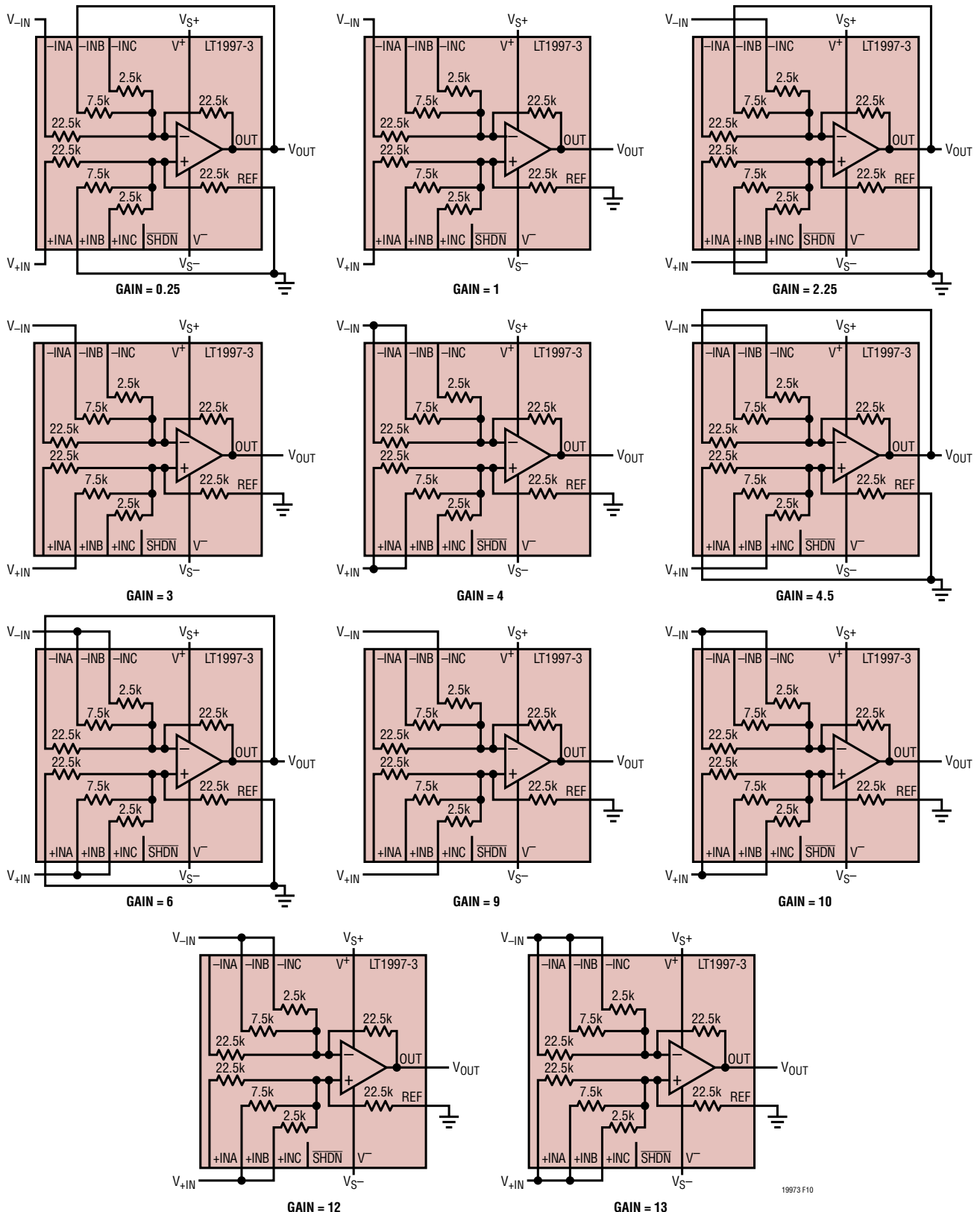
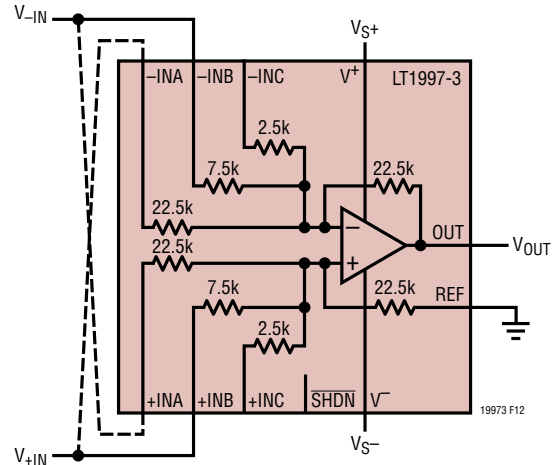
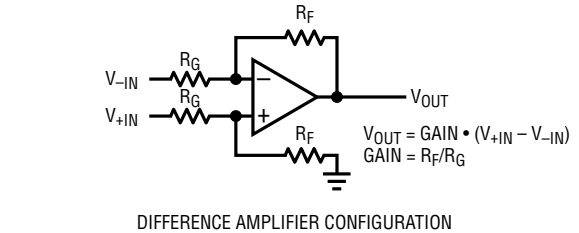


Figure 10. Many Difference Amplifier Gains Can Be Achieved by Strapping Pins

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Difference Amplifier: Additional Integer Gains Using Cross-Coupling

Figure 11 shows the basic difference amplifier as well as the LT1997-3 with cross-coupled inputs. The additional dashed connections reduce the differential gain from 3 to 2. Using this method, additional integer gains are achievable, as shown in Table 5, so that all integer gains from 1 to 13 are achieved with the LT1997-3. Note that the equations can be written by inspection from the V_{+IN} connections, and that the V_{-IN} connections are simply the opposite (swap + for - and - for +). Noise gain, bandwidth, and input impedance specifications for the various cases are also shown. Schematics of the difference amplifiers using cross-coupling are shown in Figure 12. Additional non-integer gains produced with cross-coupling are listed in Table 6.



DIFFERENCE AMPLIFIER CONFIGURATION
 IMPLEMENTED WITH THE LT1997-3, $R_F = 22.5k$, $R_G = 7.5k$, GAIN = 3
 GAIN CAN BE ADJUSTED BY CROSS-COUPLING THE INPUTS.
 MAKING THE DASHED CONNECTIONS REDUCES THE GAIN FROM 3 TO 2

Figure 11. Cross-Coupling the Inputs of the LT1997-3 Allows Additional Integer Gains to Be Constructed. The LT1997-3 Provides All Integer Gains from 1 to 13

Table 5. Connections Using Cross-Coupling. Note that Equations Can Be Written by Inspection of the V_{+IN} Column

| Gain | V_{+IN} | V_{-IN} | Equation | Noise Gain | -3dB BW (kHz) | Differential Input Impedance (k Ω) | Common Mode Input Impedance (k Ω) |
|------|------------------|------------------|-----------|------------|---------------|--|---|
| 2 | +INB, -INA | -INB, +INA | 3 - 1 | 5 | 540 | 11.25 | 14.1 |
| 5 | +INC, -INB, -INA | -INC, +INB, +INA | 9 - 3 - 1 | 14 | 222 | 3.5 | 12.1 |
| 7 | +INC, +INA, -INB | -INC, -INA, +INB | 9 + 1 - 3 | 14 | 222 | 3.5 | 12.1 |
| 8 | +INC, -INA | -INC, +INA | 9 - 1 | 11 | 277 | 4.5 | 12.4 |
| 11 | +INC, +INB, -INA | -INC, -INB, +INA | 9 + 3 - 1 | 14 | 222 | 3.5 | 12.1 |

Table 6. Additional Non-Integer Gains that Can Be Achieved Using Cross-Coupling

| Gain | V_{+IN} | V_{-IN} | OUT | GND (REF) |
|-------|------------|------------|------------|------------|
| 0.143 | +INA | -INA | +INB, -INC | -INB, +INC |
| 0.2 | -INA, +INB | +INA, -INB | -INC | +INC |
| 0.333 | +INB | -INB | +INA, -INC | -INA, +INC |

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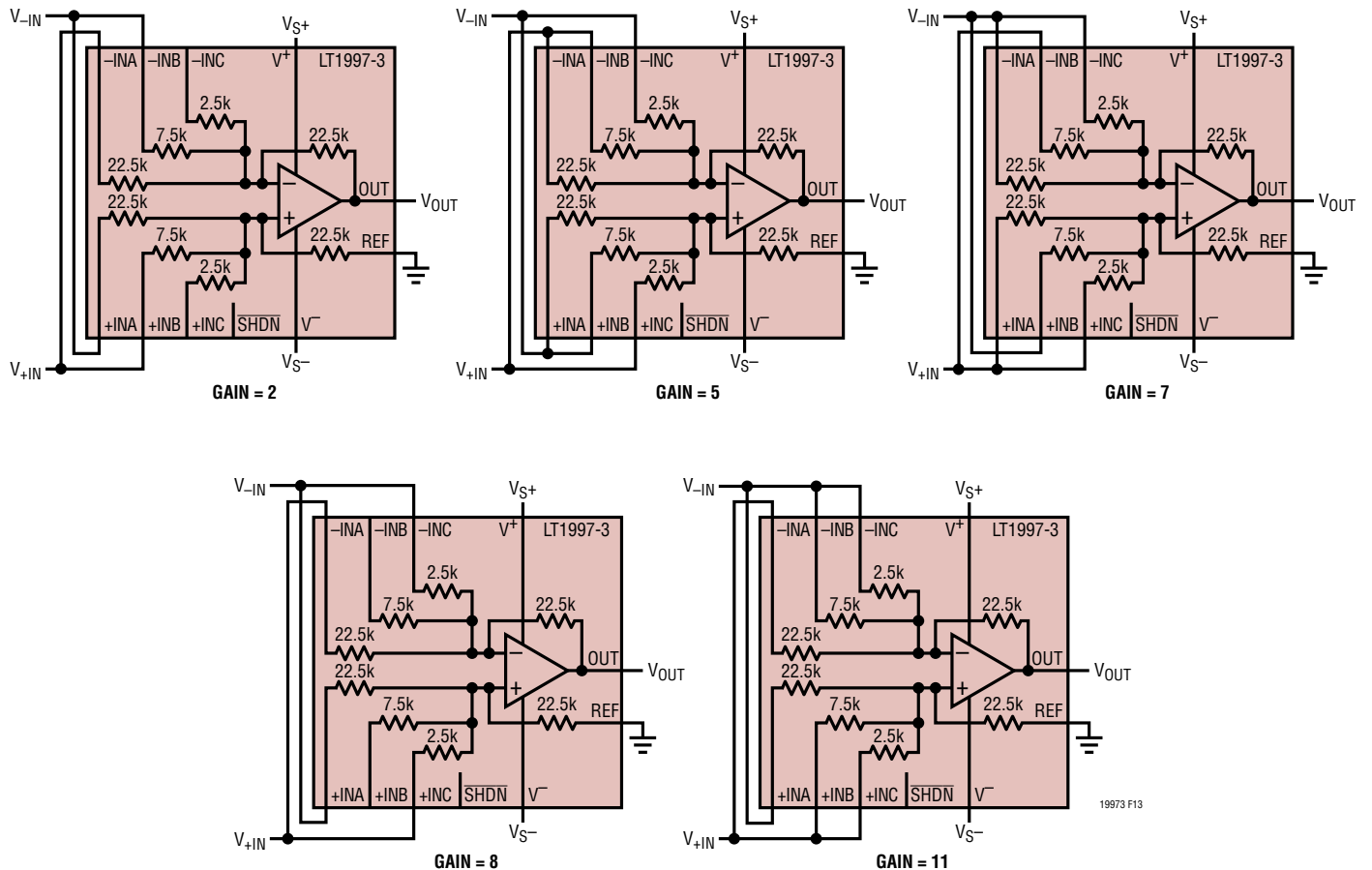


Figure 12. Integer Gain Difference Amplifiers Using Cross-Coupling

High Common Mode Voltage Difference Amplifiers

The input range of a difference amplifier can be extended by configuring the amplifier to divide the input common mode voltage. Figure 13 shows the basic circuit on the top. The effective input voltage range of the circuit is extended by the fact that resistors R_T attenuate the common mode (CM) voltage seen by the internal op amp inputs (V_{CMOP}). For the LT1997-3, the most useful resistors for R_G are the +INA and -INA 22.5kΩ resistors, because they do not have diode clamps to the V_{S-} supply and therefore can be taken beyond both rails. +INB, -INB, +INC and -INC pins can be taken 80V above V_{S-} , but not below V_{S-} . As before, the input common mode of the internal op amp is the limiting

factor and is set by the voltage at the op amp's positive input (V_{CMOP}). By superposition we can write:

$$V_{CMOP} = V_{EXT} \cdot \frac{R_F \parallel R_T}{R_G + R_F \parallel R_T} + V_{REF} \cdot \frac{R_G \parallel R_T}{R_F + R_G \parallel R_T} + V_{TERM} \cdot \frac{R_F \parallel R_G}{R_T + R_F \parallel R_G}$$

Solving for V_{EXT} :

$$V_{EXT} = \left(1 + \frac{R_G}{R_F \parallel R_T} \right) \cdot \left(\frac{V_{CMOP} - V_{REF} \cdot \frac{R_G \parallel R_T}{R_F + R_G \parallel R_T}}{-V_{TERM} \cdot \frac{R_F \parallel R_G}{R_T + R_F \parallel R_G}} \right)$$

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Given the values of the resistors in the LT1997-3, this equation has been simplified and evaluated, and the resulting equations are provided in Table 7. Substituting $V_{S+} - 1.75V$ and V_{S-} for V_{LIM} will give the valid upper and lower common mode extremes respectively for the normal operating region of the op amp. Substituting $V_{S-} + 76V$ and V_{S-} for V_{LIM} will give the valid upper and lower common mode extremes respectively for the Over-The-Top region of the op amp (see Over-The-Top Operation section of this data sheet for more detail). Following are sample calculations for the case shown in Figure 13. Note that +INC and -INC are terminated so row 3 of Table 7 provides the equation:

$$\begin{aligned} \text{MAX } V_{EXT} &= 11 \cdot (V_{S+} - 1.75) - V_{REF} - 9 \cdot V_{TERM} \\ &= 11 \cdot (10.25V) - 2.5 - 9 \cdot 12 \\ &= 2.25V \end{aligned}$$

and:

$$\begin{aligned} \text{MIN } V_{EXT} &= 11 \cdot (V_{S-}) - V_{REF} - 9 \cdot V_{TERM} \\ &= 11 \cdot (0) - 2.5 - 9 \cdot 12 \\ &= -110.5V \end{aligned}$$

If the calculated V_{EXT} voltage exceeds the 160V absolute maximum rating of the +INA, -INA pins, 160V or -160V would become the de facto common mode limit. Several more examples of high CM circuits are shown in Figure 14, Figure 15 and Figure 16 for various supplies.

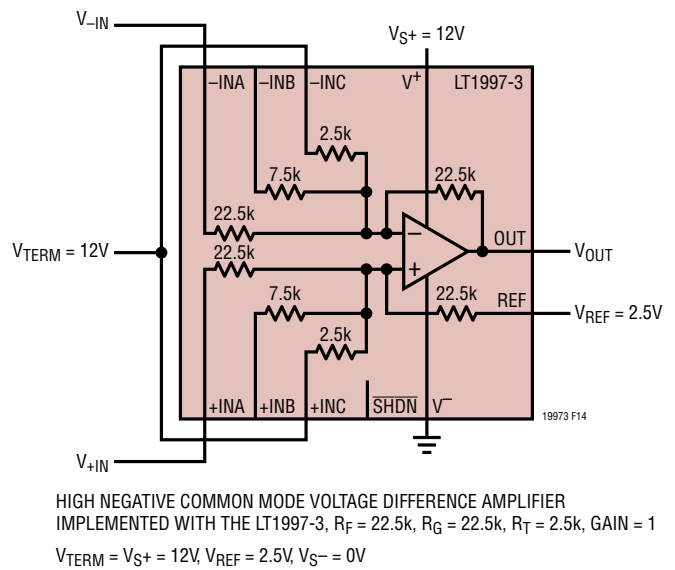
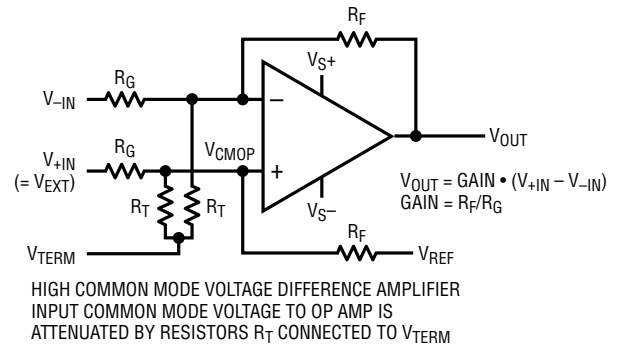


Figure 13. Extending Common Mode Input Range

Table 7. Input Common Mode Voltage Ranges for the LT1997-3 when Configured as a High Common Mode Voltage Difference Amplifier

| Gain | V_{+IN} | V_{-IN} | R_T | Noise Gain | Max, Min V_{EXT} (Substitute $V_{S+} - 1.75$ (Normal Region) or $V_{S-} + 76$ (OTT), and V_{S-} for V_{LIM}) |
|------|-----------|-----------|---|------------|---|
| 1 | +INA | -INA | | 2 | $2 \cdot V_{LIM} - V_{REF}$ |
| 1 | +INA | -INA | R_{+INB} , R_{-INB} | 5 | $5 \cdot V_{LIM} - V_{REF} - 3 \cdot V_{TERM}$ |
| 1 | +INA | -INA | R_{+INC} , R_{-INC} | 11 | $11 \cdot V_{LIM} - V_{REF} - 9 \cdot V_{TERM}$ |
| 1 | +INA | -INA | $R_{+INB} R_{+INC}$, $R_{-INB} R_{-INC}$ | 14 | $14 \cdot V_{LIM} - V_{REF} - 12 \cdot V_{TERM}$ |

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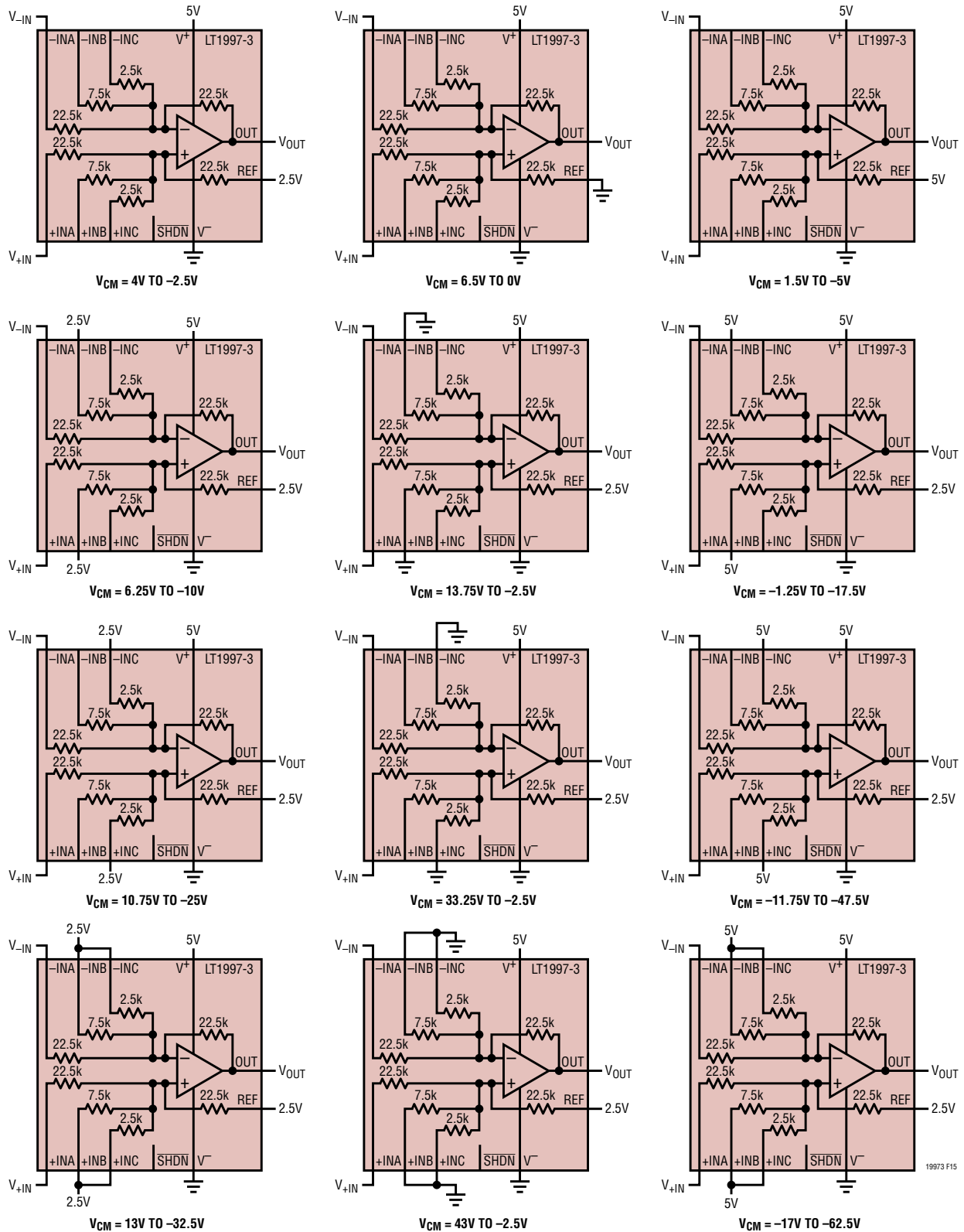


Figure 14. Common Mode Ranges for Various LT1997-3 Configurations on $V_S = 5V, 0V$, with Gain = 1. These Ranges Guarantee that the Internal Op Amp Operates in Its Normal Operating Region

APPLICATIONS INFORMATION

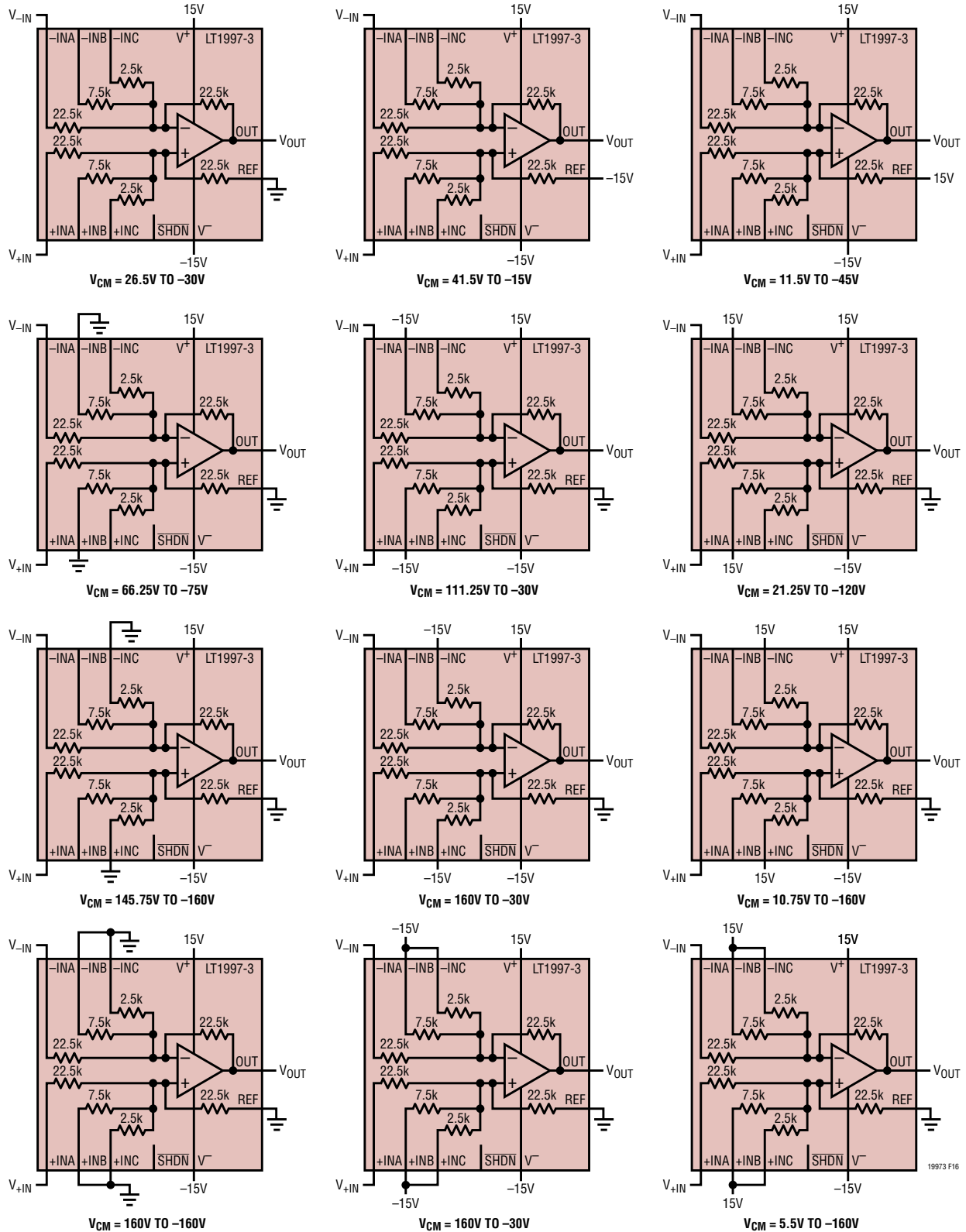


Figure 15. Common Mode Ranges for Various LT1997-3 Configurations on $V_S = \pm 15V$, with Gain = 1. These Ranges Guarantee that the Internal Op Amp Operates in Its Normal Operating Region

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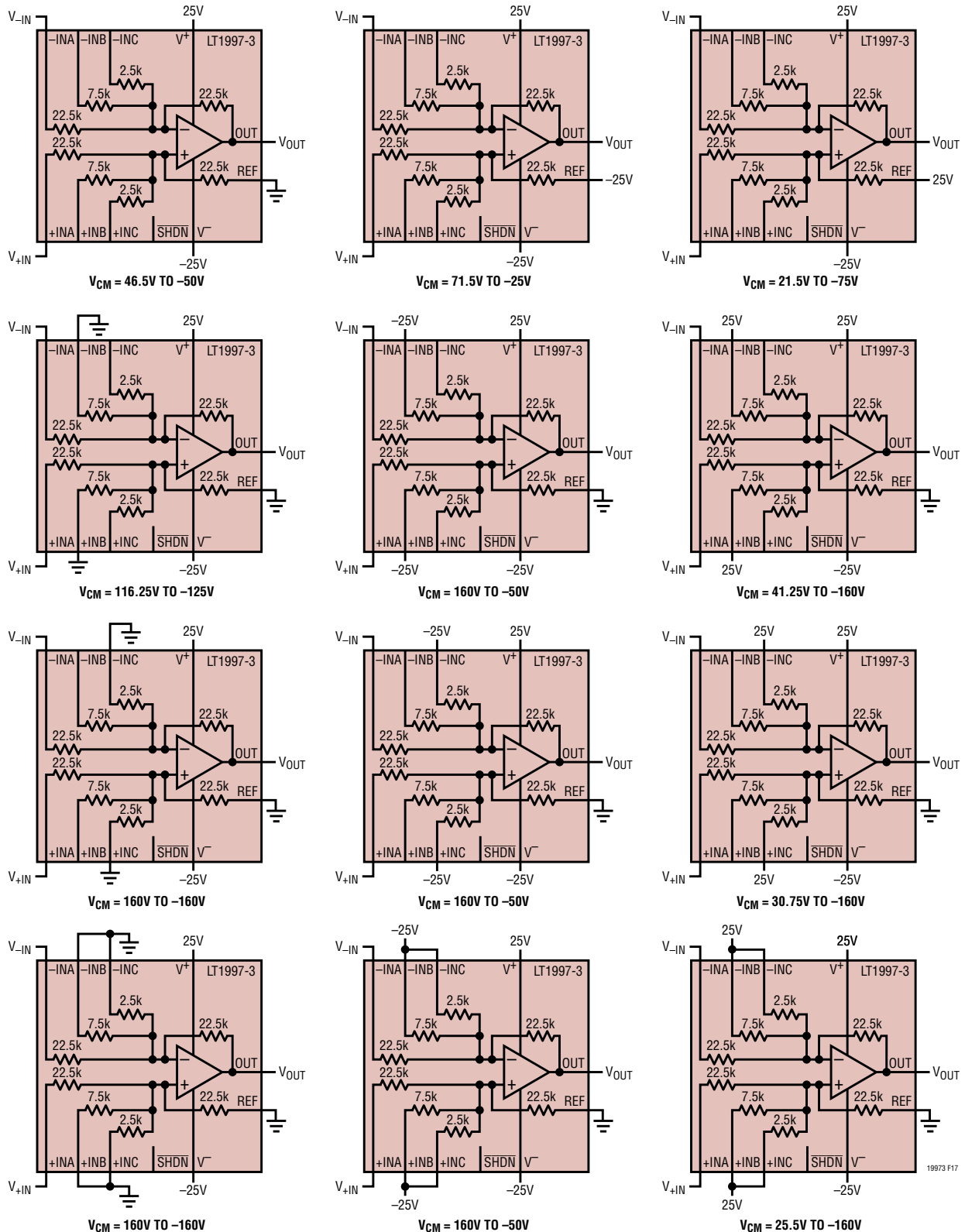


Figure 16. Common Mode Ranges for Various LT1997-3 Configurations on $V_S = \pm 25V$, with Gain = 1. These Ranges Guarantee that the Internal Op Amp Operates in Its Normal Operating Region

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Reference Resistors

In the preceding discussions, the Reference resistor is shown as a single 22.5k resistor. This is true in the DFN package. In the MSOP package the reference resistor is split into two 45k resistors (Figure 17). Tying the REF1 and REF2 pins to the same voltage produces the same reference voltage as tying the V_{REF} pin in the DFN package to that voltage. Connecting REF1 and REF2 to different voltages produces an effective reference voltage that is the average of V_{REF1} and V_{REF2} . This is especially useful when the desired reference voltage is half way between the supplies. Tying REF1 to V_{S+} and REF2 to V_{S-} produces the desired mid-supply voltage without the help of another external reference voltage (Figure 17). The ratio of R_{REF1} to R_{REF2} is very precise:

$$\frac{\Delta R}{R} = \left| \frac{R_{REF1} - R_{REF2}}{\left(\frac{R_{REF1} + R_{REF2}}{2} \right)} \right| < 60\text{ppm}$$

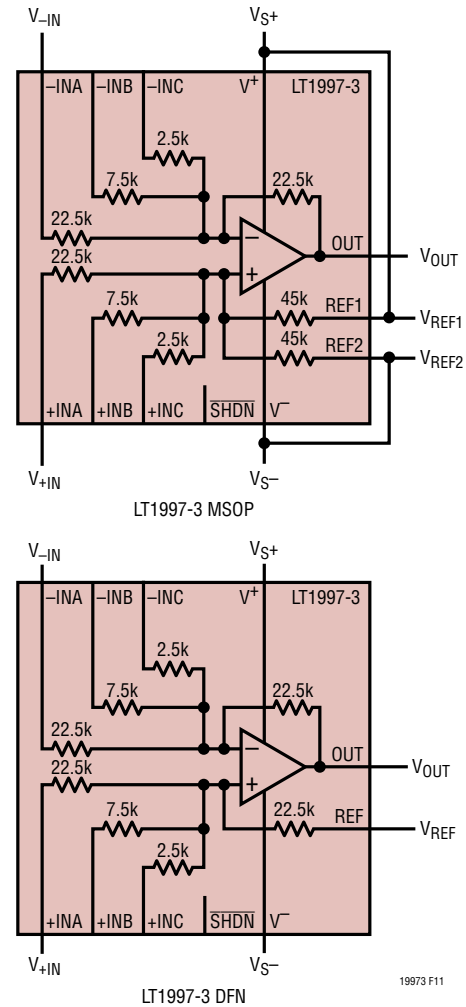


Figure 17. The LT1997-3 Reference Resistors: Split Resistors in the MSOP Package Above, Single Resistor in the DFN Package Below

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Shutdown

The LT1997-3 has a shutdown pin ($\overline{\text{SHDN}}$). Under normal operation this pin should be tied to V^+ or allowed to float. Tying this pin 2.5V or more below V^+ will cause the part to enter a low power state. The supply current is reduced to less than 25 μA and the op amp output becomes high impedance. The voltages at the input pins can still be present even in shutdown mode.

Supply Voltage

The positive supply pin of the LT1997-3 should be bypassed with a small capacitor (typically 0.1 μF) as close to the supply pins as possible. When driving heavy loads, an additional 4.7 μF electrolytic capacitor should be added. When using split supplies, the same is true for the V^- supply pin.

Output

The output of the LT1997-3 can typically swing to within 100mV of either rail with no load and is capable of sourcing and sinking approximately 25mA at 25°C. The LT1997-3 is internally compensated to drive at least 1nF of capacitance under any output loading conditions. For larger capacitive loads, a 0.22 μF capacitor in series with a 150 Ω resistor between the output and ground will compensate the amplifier to drive capacitive loads greater than 1nF. Additionally, the LT1997-3 has more gain and phase margin as its gain is increased.

Distortion

The LT1997-3 features excellent distortion performance when the internal op amp is operating in the normal operating region. Operating the LT1997-3 with the internal op amp in the over the top region will increase distortion due to the lower loop gain of the op amp. Operating the LT1997-3 with input common mode voltages that go from the normal to Over-The-Top operation will significantly degrade the LT1997-3's linearity as the op amp must transition between two different input stages. Driving resistive loads significantly smaller than the 22.5k internal feedback resistor will also degrade the amplifier's linearity performance.

Power Dissipation Considerations

Because of the ability of the LT1997-3 to operate on power supplies up to $\pm 25\text{V}$, to withstand very high input voltages and to drive heavy loads, there is a need to ensure the die junction temperature does not exceed 150°C. The LT1997-3 is housed in DF14 ($\theta_{\text{JA}} = 45^\circ\text{C/W}$, $\theta_{\text{JC}} = 3^\circ\text{C/W}$) and MS16 ($\theta_{\text{JA}} = 130^\circ\text{C/W}$) packages.

In general, the die junction temperature (T_{J}) can be estimated from the ambient temperature (T_{A}), the device's power dissipation (P_{D}) and the thermal resistance of the device and board (θ_{JA}).

$$T_{\text{J}} = T_{\text{A}} + P_{\text{D}} \cdot \theta_{\text{JA}}$$

The thermal resistance from the junction to the ambient environment (θ_{JA}) is the sum of the thermal resistance from the junction to the exposed pad (θ_{JC}) and the thermal resistance from the exposed pad to the ambient environment (θ_{CA}). The θ_{CA} value depends on how much PCB metal is connected to the exposed pad in the board. The more PCB metal that is used, the lower θ_{CA} and θ_{JA} will be.

Power is dissipated by the amplifier's quiescent current, by the output current driving a resistive load, and by the input current driving the LT1997-3's internal resistor network.

$$P_{\text{D}} = ((V_{\text{S}^+} - V_{\text{S}^-}) \cdot I_{\text{S}}) + P_{\text{OD}} + P_{\text{RESD}}$$

For a given supply voltage, the worst-case output power dissipation $P_{\text{OD(MAX)}}$ occurs with the output voltage at half of either supply voltage. $P_{\text{OD(MAX)}}$ is given by:

$$P_{\text{OD(MAX)}} = \frac{(V_{\text{S}}/2)^2}{R_{\text{LOAD}}}$$

The power dissipated in the internal resistors (P_{RESD}) depends on the manner the input resistors have been configured as well as the input voltage, the output voltage and the voltage on the REF pin. The following equations and Figure 18 show the different components of P_{RESD} corresponding to the different groups of the LT1997-3's internal resistors, assuming that the LT1997-3 is used with a dual supply configuration with +INC, -INC, and REF pins

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at ground (refer to Figure 13 for resistor terminologies used in equations below).

$$P_{RESDA} = \frac{(V_{+IN})^2}{R_G + R_F \parallel R_T}$$

$$P_{RESDB} = \frac{\left(V_{-IN} - V_{+IN} \cdot \frac{(R_F \parallel R_T)}{R_G + R_F \parallel R_T} \right)^2}{R_G}$$

$$P_{RESDC} = \frac{\left(V_{+IN} \cdot \frac{(R_F \parallel R_T)}{R_G + R_F \parallel R_T} \right)^2}{R_T}$$

$$P_{RESDD} = \frac{\left(V_{+IN} \cdot \frac{(R_F \parallel R_T)}{R_G + R_F \parallel R_T} - V_{OUT} \right)^2}{R_F}$$

$$P_{RESD} = P_{RESDA} + P_{RESDB} + P_{RESDC} + P_{RESDD}$$

In general, P_{RESD} increases with higher input voltage and lower output and REF pin voltages.

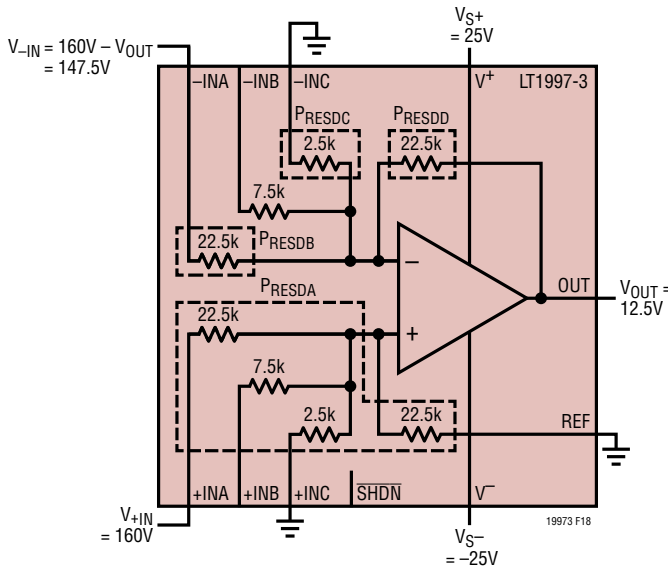


Figure 18. Power Dissipation Example

Example: For an LT1997-3 in a DFN package mounted on a PC board with a thermal resistance of 45°C/W, operating on ±25V supplies and driving a 2.5kΩ load to 12.5V with $V_{+IN} = 160V$ and $+INC = -INC = REF = 0V$, the total power dissipation is given by:

$$P_D = (50 \cdot 0.6mA) + \frac{12.5^2}{2.5k} + \frac{160^2}{24.75k} + \frac{\left(147.5 - \frac{160}{11} \right)^2}{22.5k} + \frac{\left(\frac{160}{11} \right)^2}{2.5k} + \frac{\left(\frac{160}{11} - 12.5 \right)^2}{22.5k} = 2W$$

Assuming a thermal resistance of 45°C/W, the die temperature will experience an 90°C rise above ambient. This implies that the maximum ambient temperature the LT1997-3 should operate under the above conditions is:

$$T_A = 150^\circ C - 90^\circ C = 60^\circ C$$

It is recommended that the exposed pad of the DFN package have as much PCB metal connected to it as reasonably available. The more PCB metal connected to the exposed pad, the lower the thermal resistance. Connecting a large amount of PCB metal to the exposed pad can reduce the θ_{JA} to even less than 45°C/W. Use multiple vias from the exposed pad to the V^- plane. The exposed pad is electrically connected to the V^- pin. In addition, a heat sink may be necessary if operating near maximum junction temperature.

The MSOP package has no exposed pad and a higher thermal resistance ($\theta_{JA} = 130^\circ C/W$). It should not be used in applications which have a high ambient temperature, require driving a heavy load, or require an extreme input voltage.

Thermal Shutdown

For safety, the LT1997-3 will enter shutdown mode when the die temperature rises to approximately 163°C. This thermal shutdown has approximately 9°C of hysteresis requiring the die temperature to cool 9°C before enabling the amplifier again.

APPLICATIONS INFORMATION

ESD Protection

The LT1997-3 is protected by a number of ESD structures. The structures are shown in Figure 19.

The ESD structures serve to protect the internal circuitry but also limit signal swing on certain nodes. The structures on the +INB, -INB, +INC, -INC pins and on the internal op amp inputs limit the voltage on these nodes to 0.3V below V^- and 80V above V^- . The voltage on the REF (DFN), REF1 (MSOP) and REF2 (MSOP) pins are limited to 0.3V below V^- and 60V above V^- . The voltage on the SHDN pin is limited to 0.3V below V^- and 0.3V above V^+ .

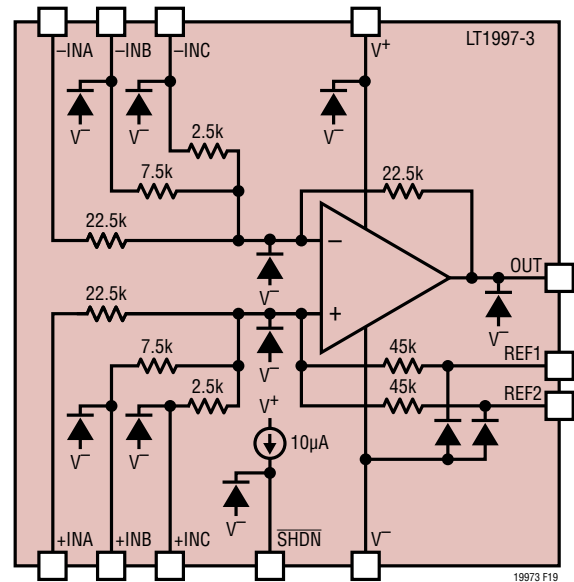
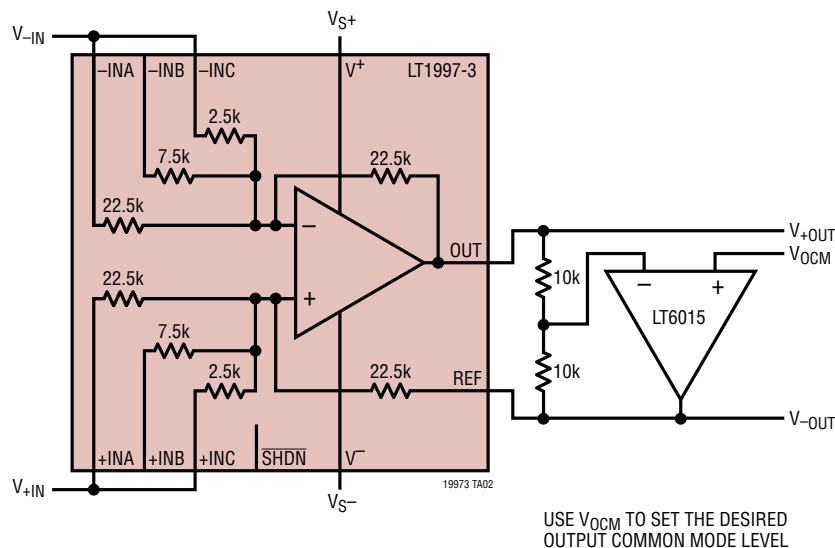


Figure 19. ESD Protection

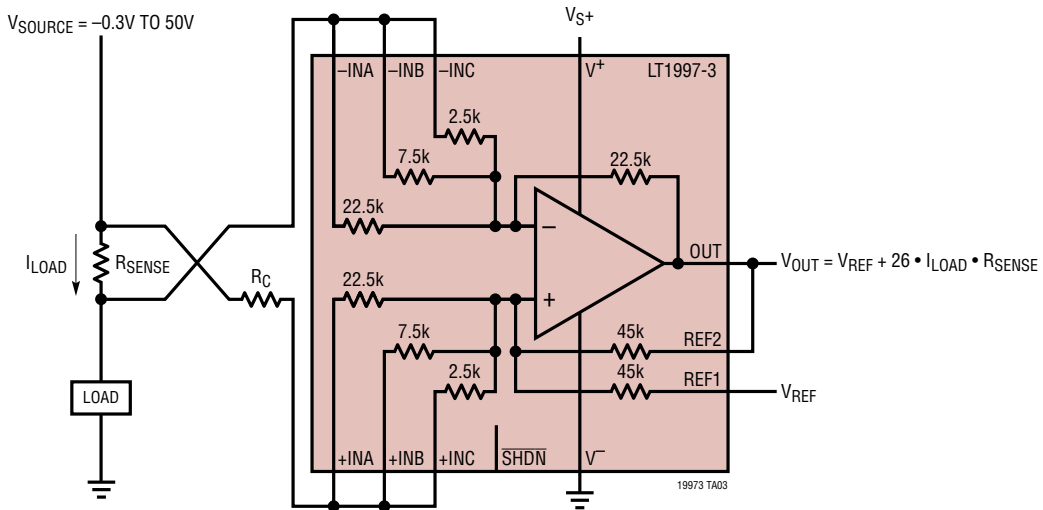
TYPICAL APPLICATIONS

Differential Input/Output Gain of 10 Amplifier

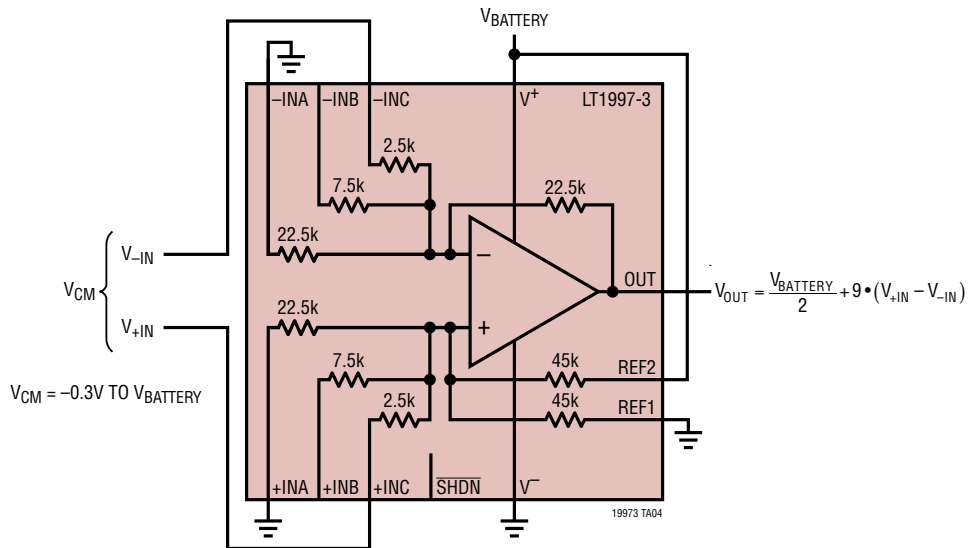


TYPICAL APPLICATIONS

Bidirectional Current Sense Amplifier



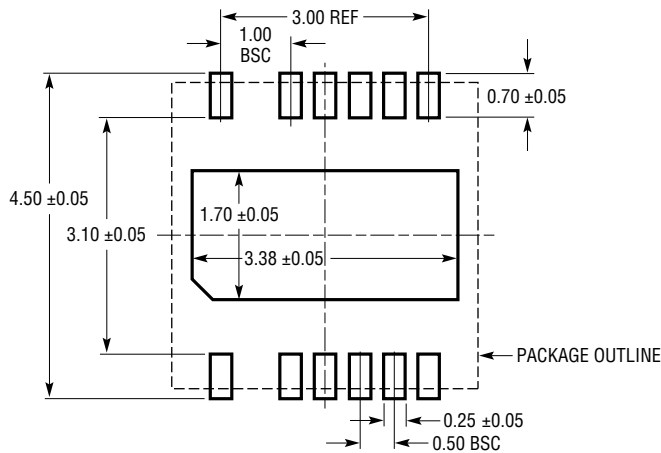
Precision RRIO Single-Supply Difference Amplifier



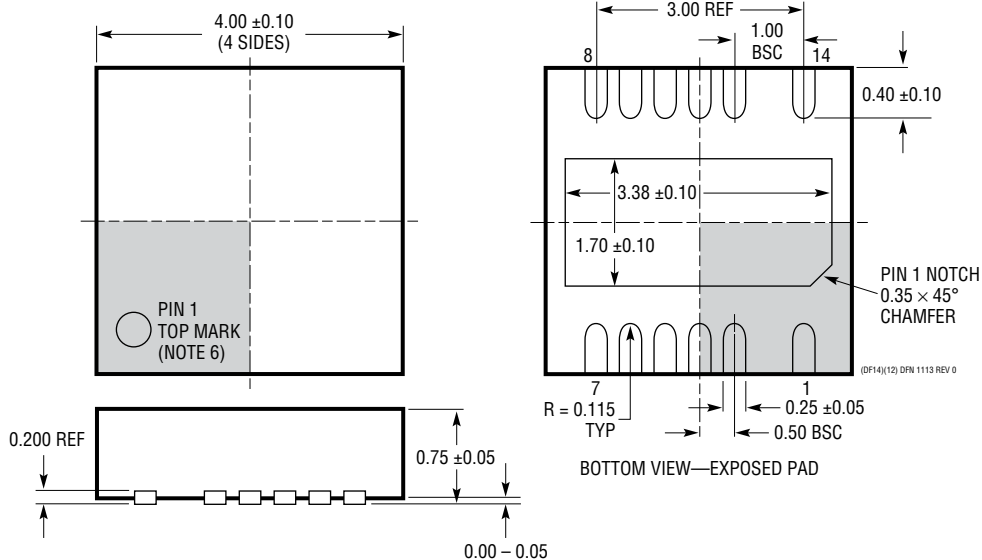
PACKAGE DESCRIPTION

Please refer to <http://www.linear.com/product/LT1997-3#packaging> for the most recent package drawings.

DF Package 14(12)-Lead Plastic DFN (4mm × 4mm) (Reference LTC DWG # 05-08-1963 Rev 0)



RECOMMENDED SOLDER PAD PITCH AND DIMENSIONS
APPLY SOLDER MASK TO AREAS THAT ARE NOT SOLDERED

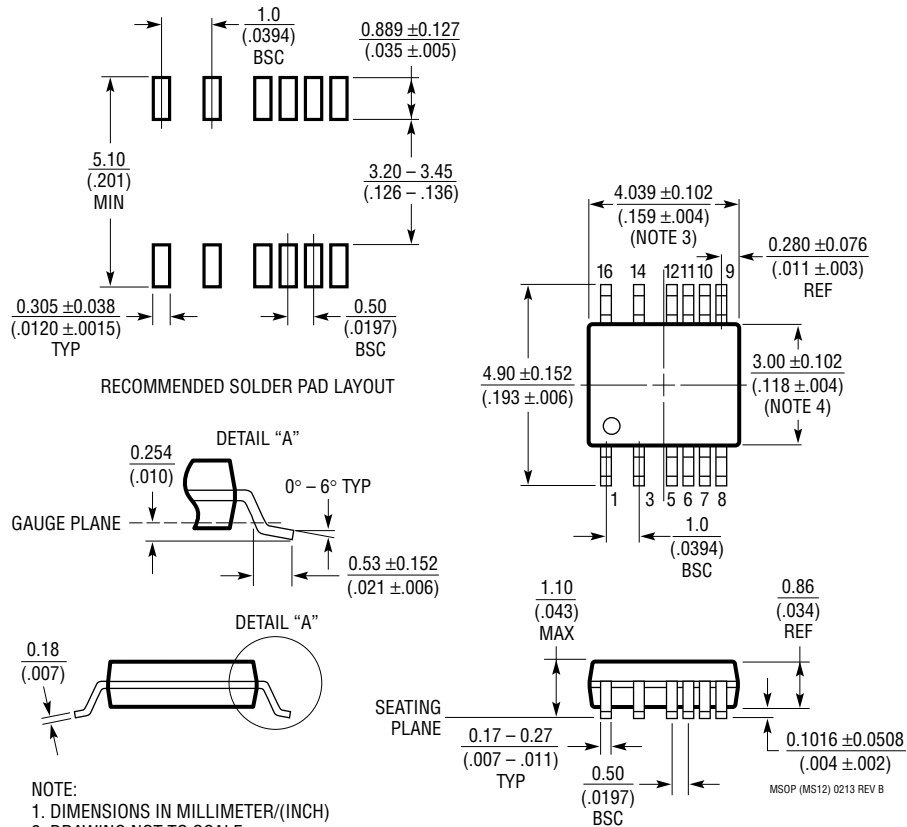


- NOTE:
1. PACKAGE OUTLINE DOES NOT CONFORM TO JEDEC MO-229
 2. DRAWING NOT TO SCALE
 3. ALL DIMENSIONS ARE IN MILLIMETERS
 4. DIMENSIONS OF EXPOSED PAD ON BOTTOM OF PACKAGE DO NOT INCLUDE MOLD FLASH. MOLD FLASH, IF PRESENT, SHALL NOT EXCEED 0.15mm ON ANY SIDE
 5. EXPOSED PAD SHALL BE SOLDER PLATED
 6. SHADED AREA IS ONLY A REFERENCE FOR PIN 1 LOCATION ON THE TOP AND BOTTOM OF PACKAGE

PACKAGE DESCRIPTION

Please refer to <http://www.linear.com/product/LT1997-3#packaging> for the most recent package drawings.

MS Package 16 (12)-Lead Plastic MSOP with 4 Pins Removed (Reference LTC DWG # 05-08-1847 Rev B)



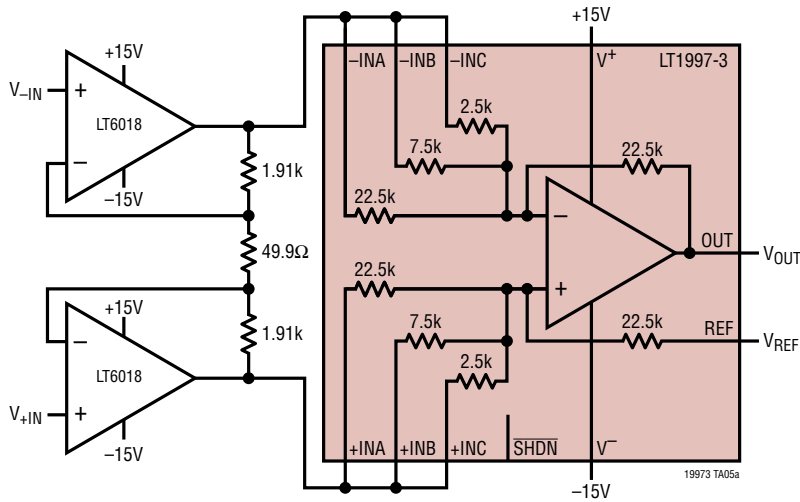
- NOTE:
1. DIMENSIONS IN MILLIMETER/(INCH)
 2. DRAWING NOT TO SCALE
 3. DIMENSION DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS.
MOLD FLASH, PROTRUSIONS OR GATE BURRS SHALL NOT EXCEED 0.152mm (.006") PER SIDE
 4. DIMENSION DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSIONS.
INTERLEAD FLASH OR PROTRUSIONS SHALL NOT EXCEED 0.152mm (.006") PER SIDE
 5. LEAD COPLANARITY (BOTTOM OF LEADS AFTER FORMING) SHALL BE 0.102mm (.004") MAX

REVISION HISTORY

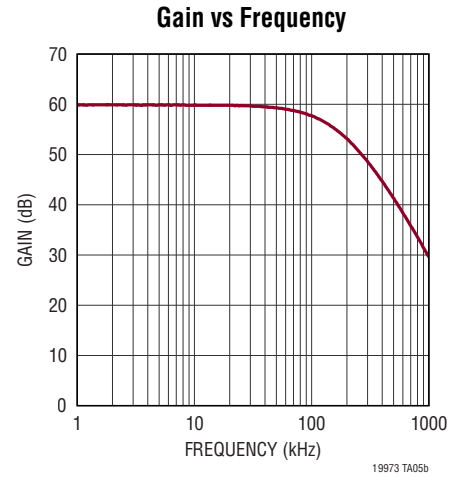
| REV | DATE | DESCRIPTION | PAGE NUMBER |
|-----|-------|--|-------------|
| A | 04/18 | Updated Electrical Characteristics, R_{IN} Input Impedance Conditions Differential | 5 |
| | | Updated Electrical Characteristics Note 7 | 6 |
| | | Updated Pin Functions, REF2 (NA/Pin 7) | 13 |

TYPICAL APPLICATION

Low Noise, High CMRR Instrumentation Amplifier



INPUT REFERRED NOISE = $2.1\text{nV}/\sqrt{\text{Hz}}$
 CMRR = 140dB





RELATED PARTS

| PART NUMBER | DESCRIPTION | COMMENTS |
|--------------------------------------|---|--|
| LT6375 | $\pm 270\text{V}$ Common Mode Voltage Difference Amplifier | 3.3V to 50V Operation, CMRR > 97dB, Input Voltage = $\pm 270\text{V}$ |
| LT1990 | $\pm 250\text{V}$ Input Range Difference Amplifier | 2.7V to 36V Operation, CMRR > 70dB, Input Voltage = $\pm 250\text{V}$ |
| LT1991 | Precision, 100 μA Gain Selectable Amplifier | 2.7V to 36V Operation, 50 μV Offset, CMRR > 75dB, Input Voltage = $\pm 60\text{V}$ |
| LT1996 | Precision, 100 μA Gain Selectable Amplifier | Micropower, Pin Selectable Up to Gain = 118 |
| LT1999 | High Voltage, Bidirectional Current Sense Amplifier | -5V to 80V, 750 μV , CMRR 80dB at 100kHz, Gain: 10V/V, 20V/V, 50V/V |
| LT6015/LT6016/LT6017 | Single, Dual, and Quad Over-The-Top Precision Op Amp | 3.2MHz, 0.8V/ μs , 50 μV V_{OS} , 3V to 50V V_{S} , 0.335mA I_{S} , RRIO |
| LT6018 | 33V, Ultralow Noise, Precision Op Amp | V_{OS} : 50 μV , GBW: 15MHz, SR: 30V/ μs , en: 1.2nV/ $\sqrt{\text{Hz}}$, I_{S} : 7.2mA |
| LTC6090 | 140V Operational Amplifier | 50pA I_{B} , 1.6mV V_{OS} , 9.5V to 140V V_{S} , 4.5mA I_{S} , RR Output |
| LT6108 | High Side Current Sense Amplifier with Reference and Comparator with Shutdown | 2.7V to 60V, 125 μV , Resistor Set Gain, $\pm 1.25\%$ Threshold Error |
| LT1787/LT1787HV | Precision, Bidirectional High Side Current Sense Amplifier | 2.7V to 60V Operation, 75 μV Offset, 60 μA Current Draw |
| LT6100 | Gain-Selectable High Side Current Sense Amplifier | 4.1V to 48V Operation, Pin-Selectable Gain: 10V/V, 12.5V/V, 20V/V, 25V/V, 40V/V, 50V/V |
| LTC6101/LTC6101HV | High Voltage High Side Current Sense Amplifier | 4V to 60V/5V to 100V Operation, External Resistor Set Gain, SOT23 |
| LTC6102/LTC6102HV | Zero Drift High Side Current Sense Amplifier | 4V to 60V/5V to 100V Operation, $\pm 10\mu\text{V}$ Offset, 1 μs Step Response, MSOP8/DFN Packages |
| LTC6104 | Bidirectional, High Side Current Sense | 4V to 60V, Gain Configurable, 8-Pin MSOP Package |

Looking for pricing, stock, or lifecycle information?

Click below to explore more details on WIN SOURCE:

-  [View LT1997HDF-3#PBF on WIN SOURCE](#)
-  [Analog Devices Inc. Information](#)

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-  Shortage Management
-  Alternative Solution
-  Excess Inventory Management